

### Ultra-low-power wireless 32-bit MCUs Arm®-based Cortex®-M0+ with Bluetooth® Low Energy and 2.4 GHz radio solution



## Features

**Includes ST state-of-the-art patented technology.**

**Bluetooth® Low Energy system-on-chip supporting Bluetooth 5.4 specifications**

- 2 Mbps data rate
- Long range (Coded PHY)
- Advertising extensions
- Channel selection algorithm #2
- GATT caching
- LE Ping procedure
- Periodic advertising and periodic advertising sync transfer
- Periodic advertising with response
- Advertising coding selection
- Encrypted advertising
- LE L2CAP connection-oriented channel
- LE power control and path loss monitoring
- LE channel classification
- Enhanced ATT (EATT)
- Connection subrating
- Broadcast isochronous streams (BIS)
- Connection isochronous streams (CIS)

Product status	
STM32WB06xC	STM32WB06CC
	STM32WB06KC
STM32WB07xC	STM32WB07CC
	STM32WB07KC

## Radio

- Rx sensitivity level: -97 dBm @ 1 Mbps, -104 dBm @ 125 kbps (long range)
- Programmable output power up to +8 dBm (at antenna connector)
- Data rate supported: 2 Mbps, 1 Mbps, 500 kbps, and 125 kbps
- 128 physical connections
- Integrated balun
- Support for external PA
- STM32WB0xxC core coprocessor (DMA based) for Bluetooth® Low Energy timing critical operation
- 2.4 GHz proprietary radio driver
- Suitable for systems requiring compliance with the following radio frequency regulations: ETSI EN 300 328, EN 300 440, FCC CFR47 part 15, ARIB STD-T66
- Available integrated passive device (IPD) companion chip for optimized matching and filtering

## Ultra-low-power features (ultra-low-power devices)

- 10 nA in Shutdown mode (1.8 V)
- 0.6 µA in Deepstop mode (with external LSE and Bluetooth® Low Energy wake-up sources, 1.8 V)

- 0.9 µA in Deepstop mode (with internal LSI and Bluetooth® Low Energy wake-up sources, 1.8 V)
- 4.3 mA peak current in Tx (@ 0 dBm, 3.3 V)
- 3.4 mA peak current in Rx (@ sensitivity level, 3.3 V)
- High performance and ultralow power Arm® Cortex®-M0+ 32-bit, running up to 64 MHz
- Dynamic current consumption: 16.5 µA/MHz
- Operating supply voltage: from 1.7 to 3.6 V

### Security

- Flash read/write protection
- SWD disabling
- Secure bootloader
- True random number generator (RNG)
- Hardware encryption AES maximum 128-bit security coprocessor
- Hardware public key accelerator (PKA)
- CRC calculation unit
- 64-bit unique ID

### Clock management

- High efficiency embedded SMPS step-down converter with intelligent bypass mode
- Ultra-low-power power-on-reset (POR) and power-down-reset (PDR)
- Programmable voltage detector (PVD)
- Fail-safe 32 MHz crystal oscillator with integrated trimming capacitors
- 32 kHz crystal oscillator
- Internal low-power 32 kHz RO

### Memories

- On-chip nonvolatile flash memory of 256 Kbytes
- On-chip RAM of 64 Kbytes or 32 Kbytes
- One-time-programmable (OTP) memory area of 1 Kbyte
- Embedded UART bootloader
- Ultra-low-power modes with or without timer and RAM retention

### Security

- Flash read/write protection
- SWD disabling
- Secure bootloader
- True random number generator (RNG)
- Hardware encryption AES maximum 128-bit security coprocessor
- Hardware public key accelerator (PKA)
- CRC calculation unit
- 64-bit unique ID

### System peripherals

- 1x DMA controller with eight channels supporting ADC, SPI, I2C, USART, and LPUART
- 1x SPI
- 2x SPI/I2S
- 2x I2C (SMBus/PMBus)
- 1x PDM (digital microphone interface)
- 1x LPUART

- 1x USART (ISO 7816 smartcard mode, IrDA, SPI controller, and modbus)
- 1x independent WDG
- 1x real-time clock (RTC)
- 1x independent SysTick
- 1x 16-bit, six channel advanced timer

#### **General-purpose inputs/outputs**

- Quadrature decoder
- Up to 32 fast I/Os
- 28 of them with wake-up capability
- 31 of them 5 V tolerant

#### **Analog peripherals**

- 12-bit ADC with eight input channels, up to 16 bits with a decimation filter
- Battery monitoring
- Analog watchdog
- Analog mic I/F with PGA

#### **Debug**

- Development support
- Serial wire debug (SWD)
- Four breakpoints and two watchpoints

**All packages are ECOPACK2 compliant.**

## 1 Introduction

This document provides information on STM32WB0xxC devices, such as description, functional overview, pin assignment and definition, electrical characteristics, packaging and ordering information.

It must be read in conjunction with the STM32WB0xxC reference manual (RM0530).

For information on the device errata with respect to the datasheet and reference manual, refer to the STM32WB0xxC errata sheet (ES0632).

For information on the Arm® Cortex®-M0+ core, refer to the Cortex-M0+ Technical Reference Manual, available from the [www.arm.com](http://www.arm.com) website.

For information on Bluetooth®, refer to <http://www.bluetooth.com> website.

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## 2 Description

The STM32WB0xxC is an ultra-low-power programmable Bluetooth® Low Energy wireless SoC solution. It embeds STMicroelectronics state-of-art 2.4 GHz RF radio IPs combining unparalleled performance with extremely long-battery lifetime. It is compliant with Bluetooth® Low Energy SIG core specification version 5.4 addressing point-to-point connectivity and Bluetooth Mesh networking and allows large-scale device networks to be established in a reliable way. The STM32WB0xxC is also suitable for 2.4 GHz proprietary radio wireless communication to address ultra-low latency applications.

The STM32WB0xxC embeds a Cortex®-M0+ microcontroller that can operate up to 64 MHz and also the BlueNRG core coprocessor (DMA based) for Bluetooth® Low Energy timing critical operations.

In addition, the STM32WB0xxC provides enhanced security hardware support by dedicated hardware functions: True random number generator (RNG), encryption AES maximum 128-bit security coprocessor, public key accelerator (PKA), CRC calculation unit, 64-bit unique ID, flash memory read and write protection.

The STM32WB0xxC can be configured to support standalone or network processor applications. In the first configuration, the STM32WB0xxC operates as a single device in the application for managing both the application code and the Bluetooth® Low Energy stack.

The STM32WB0xxC embeds high-speed and flexible memory types: flash memory of 256 Kbytes, RAM memory of 64 Kbytes, one-time-programmable (OTP) memory area of 1 Kbyte, ROM memory of 7 Kbytes (ST reserved area).

Direct data transfer between memory and peripherals and from memory-to-memory is supported by eight DMA channels with a full flexible channel mapping by the DMAMUX peripheral.

The STM32WB0xxC embeds a 12-bit ADC, allowing measurements of up to eight external sources and up to three internal sources, including battery monitoring and a temperature sensor.

The STM32WB0xxC has a low-power RTC and one advanced 16-bit timer.

The STM32WB0xxC features standard and advanced communication interfaces:

1x SPI, 2x SPI/I2S, 1x LPUART, 1x USART supporting ISO 7816 (smartcard mode), IrDA, and modbus mode, 2x I<sup>2</sup>C supporting SMBus/PMBus, 1x channel PDM.

The STM32WB0xxC operates in the -40 to +105°C temperature range from a 1.7 V to 3.6 V power supply. A comprehensive set of power-saving modes enables the design of low-power applications.

The STM32WB0xxC integrates a high efficiency SMPS step-down converter and an integrated PDR circuitry with a fixed threshold that generates a device reset when the V<sub>DD</sub> drops under 1.65 V.

The STM32WB0xxC comes in different package versions supporting up to:

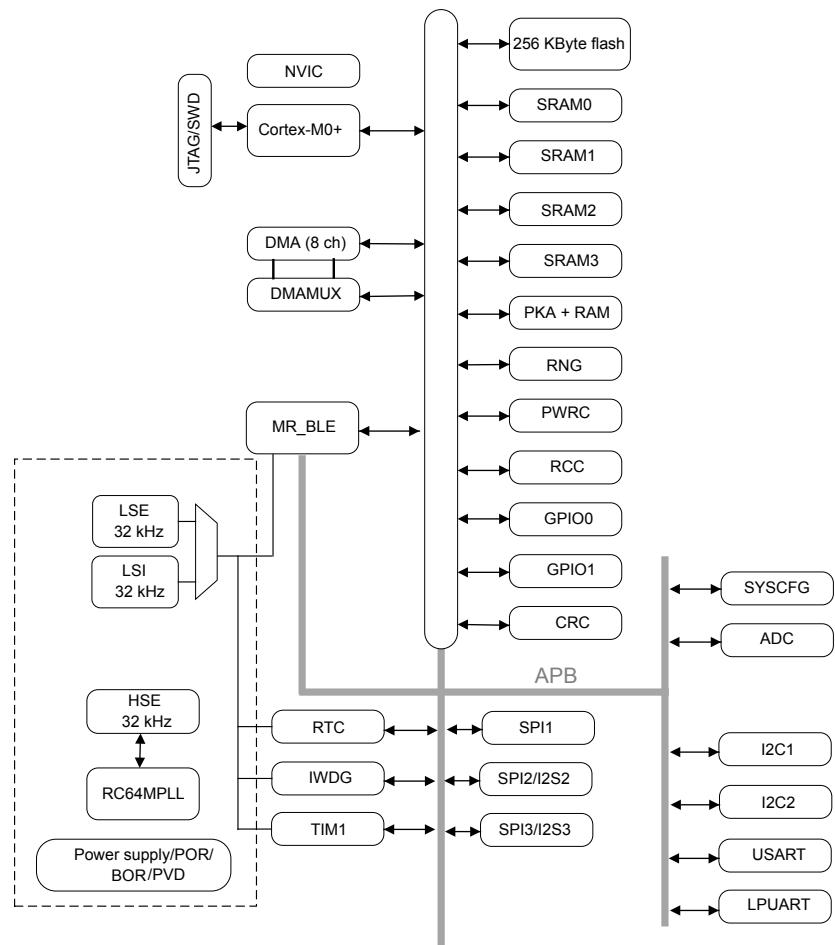
32 I/Os for the VFQFPN48 package, 20 I/Os for the VFQFPN32 package, 30 I/Os for the WLCSP49 package.

Refer to [Table 1](#) for the list of peripherals available on each part number.

**Table 1.** Device features and peripheral counts

Peripherals	STM32WB06KC	STM32WB06CC	STM32WB07KC	STM32WB07CC			
Flash memory (Kbytes)	256 Kbytes						
SRAM (Kbytes)	SRAM0	16 Kbytes	16 Kbytes	16 Kbytes			
	SRAM1	16 Kbytes	16 Kbytes	16 Kbytes			
	SRAM2	-	16 Kbytes	16 Kbytes			
	SRAM3	-	16 Kbytes	16 Kbytes			
Bluetooth® Low Energy	Yes						
Timers	General purpose	1 x 16-bit, 6 channel advanced timer					
	2.4 GHz proprietary radio timer low-power	32-bit					
	SysTick	1					
Real-time clock (RTC)	Yes						
Random number generator	Yes						
AES	Yes						
Public key accelerator (PKA)	Yes						
Communication interfaces	SPI/I2S	2 with I2S feature					
	I2C	1					
	USART	1					
	LPUART	1					
12-bit ADC with 1 PDM	Number of channels	8					
GPIOs	32						
Wakeup pins	28						
Maximum CPU frequency (MHz)	64						
Operating voltage	1.7 to 3.6 V						
Operating temperature	Temperature range: -40 to 105 °C						
Packages	VFQFPN32 5 x 5 mm, 0.50 mm pitch, very fine pitch quad flat no lead package						
	VFQFPN48 6 x 6 mm, 0.40 mm pitch, very fine pitch quad flat no lead package						
	WLCSP49 3.140 x 3.140 mm, 0.40 mm pitch, wafer level chip scale array package						

Figure 1 shows the general block diagram of the device family.

**Figure 1. STM32WB0xxC block diagram**

DT58101V1

## 3 Functional overview

### 3.1

#### ARM Cortex-M0+ core with MPU

The STM32WB0xxC contains an ARM Cortex-M0+ microcontroller core. The Cortex-M0+ was developed to provide a low-cost platform that meets the needs of CPU implementation, with a reduced pin count and low-power consumption, while delivering outstanding computational performance and an advanced response to interrupts. The Cortex-M0+ can run from 1 MHz up to 64 MHz.

The Cortex-M0+ processor is built on a highly area and power optimized 32-bit processor core, with a 2-stage pipeline Von Neumann architecture. The processor delivers exceptional energy efficiency through a small but powerful instruction set and extensively optimized design, providing high-end processing hardware including a single-cycle multiplier.

The interrupts are handled by the Cortex-M0+ Nested Vector Interrupt Controller (NVIC). The NVIC controls specific Cortex-M0+ interrupts as well as the STM32WB0xxC peripheral interrupts. With its embedded ARM core, the STM32WB0xxC family is compatible with all ARM tools and software.

### 3.2

#### Memory protection unit (MPU)

The MPU is used to manage accesses to memory to prevent one task from accidentally corrupting the memory or resources used by any other active task. This memory area is organized into up to 8 protected areas. The protection area sizes are between 32 bytes and the whole 4 gigabytes of addressable memory.

The MPU is especially helpful for applications where some critical or certified code has to be protected against the misbehavior of other tasks. It is usually managed by an RTOS (real-time operating system). If a program accesses a memory location that is prohibited by the MPU, the RTOS can detect it and take action. In an RTOS environment, the kernel can dynamically update the MPU area settings, based on the process to be executed.

The MPU is optional and can be bypassed for applications that do not need it.

### 3.3

#### Memories

##### 3.3.1

##### Embedded flash memory

The flash memory controller implements the erase and program Flash memory operation. The flash controller also implements the read and write protection.

The flash memory features are:

- Memory organization:
  - 1 bank of 256 kB
  - Page size: 2 kB
  - Page number 128
- 32-bit wide data read/write
- Page erase and mass erase

The flash memory controller features are:

- Flash memory read operations
- Flash memory write operations: single data write or 4x32-bits burst write
- Flash memory erase operations
- Page write protect mechanism

##### 3.3.2

##### Embedded SRAM

The STM32WB0xxC has a total of 64 kB of embedded SRAM, split into four banks as shown in the following table:

Table 2. SRAM overview

SRAM bank	Size	Address	Retained in Deepstop
SRAM0	16 kB	0x2000 0000	Always

SRAM bank	Size	Address	Retained in Deepstop
SRAM1	16 kB	0x2000 4000	Programmable by the user
SRAM2	16 kB	0x2000 8000	Programmable by the user
SRAM3	16 kB	0x2000 C000	Programmable by the user

### 3.3.3

#### Embedded ROM

The STM32WB0xxC has a total of 7 Kbytes of embedded ROM. This area is ST reserved and contains:

- The UART bootloader from which the CPU boots after each reset (first 6 Kbytes of ROM memory)
- Some ST reserved values including the ADC trimming values (the last 1 Kbyte of ROM memory)

### 3.3.4

#### Embedded OTP

The one-time-programmable (OTP) is a memory of 1 Kbyte dedicated for user data. The OTP data cannot be erased.

The user can protect the OTP data area by writing the last word at address 0x1000 1BFC and by performing a system reset. This operation freezes the OTP memory from further unwanted write operations.

### 3.4

## Security and safety

The STM32WB0xxC contains many security blocks for the Bluetooth® Low Energy and the host application.

It includes:

- Flash read/write protections
- As protection against potential hacker attacks, the SWD access can be disabled
- Secure bootloader
- Customer storage of the Bluetooth® Low Energy keys
- True random number generator (RNG)
- Private key accelerator (PKA) including:
  - Elliptic curve Diffie-Hellman (ECDH) public-private key pair calculation accelerator
  - Based on the Montgomery method for fast modular multiplications
  - Built-in Montgomery domain inward and outward transformations
    - AMBA® AHB lite target interface with a reduced command set
- Cyclic redundancy check calculation unit (CRC)

### 3.5

## Boot modes

After the CPU boots, the application software has the capability to modify the memory map at address 0x0000 0000. This modification is carried out by programming the REMAP bit in the flash memory controller.

The following memory can be remapped:

- Main flash memory
- SRAM0 memory

### 3.6

## Radio system

### 3.6.1

#### RF subsystem

The STM32WB0xxC embeds an ultralow power radio, compliant with the Bluetooth® Low Energy specification. The Bluetooth® Low Energy features 1 Mbps and 2 Mbps transfer rates as well as long range options (125 kbps, 500 kbps), supports multiple roles simultaneously acting at the same time as a Bluetooth® Low Energy sensor and a hub device.

The Bluetooth® Low Energy protocol stack is implemented by an efficient system partitioned as follows:

- Hardware part: BlueCore handling time-critical and time consuming Bluetooth® Low Energy protocol parts
- Firmware part: Arm® Cortex®-M0+ core handling nontime critical Bluetooth® Low Energy protocol parts

### 3.6.1.1 RF front-end block diagram

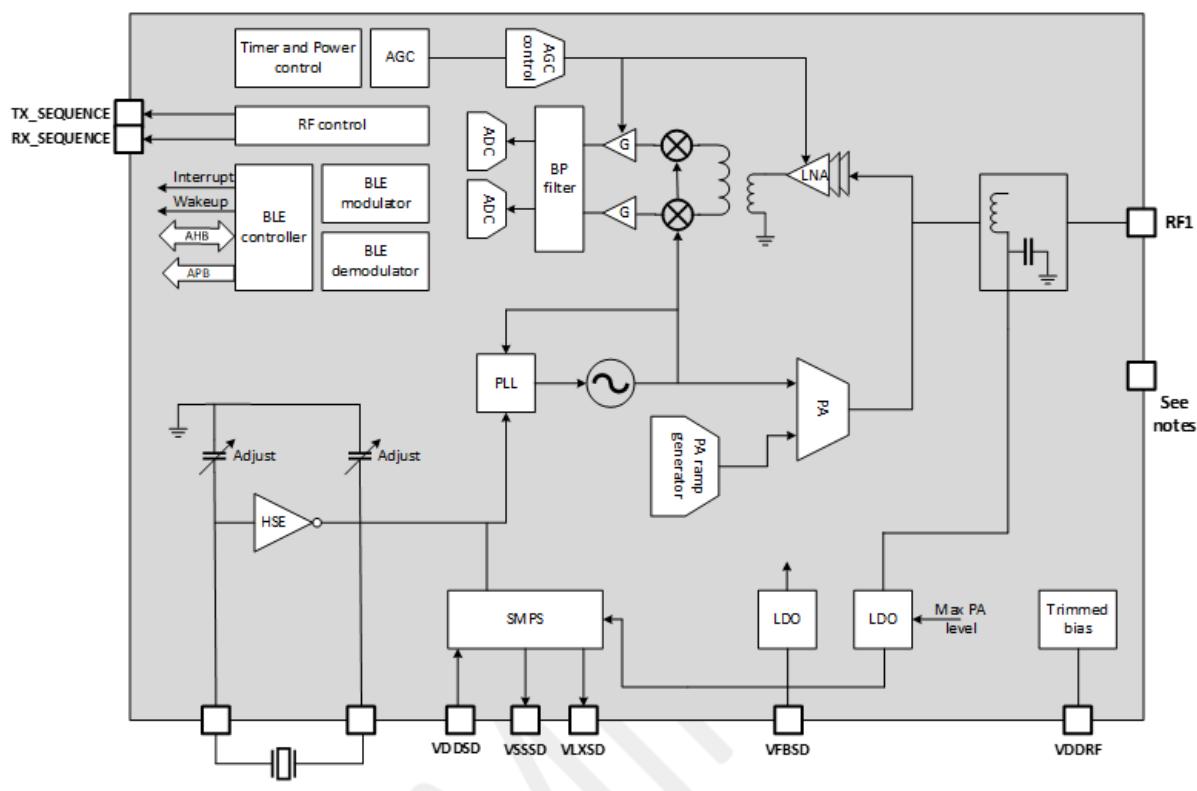
The RF front-end is based on a direct modulation of the carrier in Tx, and uses a low IF architecture in Rx mode.

Thanks to an internal transformer with RF pins, the circuit directly interfaces the antenna (single ended connection, impedance close to  $50\ \Omega$ ). The natural band pass behavior of the internal transformer simplifies outside circuitry aimed at harmonic filtering and out of band interferer rejection.

In transmit mode, the maximum output power is user selectable through the programmable LDO voltage of the power amplifier. A linearized, smoothed analog control offers a clean power ramp-up.

In receive mode, the automatic gain control (AGC) can reduce the gain in both the RF and IF stages, optimizing interferer rejection. Thanks to the use of complex filtering and a highly accurate I/Q architecture, high sensitivity, and excellent linearity can be achieved.

**Figure 2. STM32WB0xxC RF block diagram**



Note:

VFQFPN32 and VFQFPN48: VSS through exposed pad, and VSSRF pins must be connected to ground plane.

WLCSP49: VSSRF pins must be connected to ground plane.

### 3.6.1.2 IPDs for STM32WB06xC and STM32WB07xC

Table 3 lists the available IPD variants for the STM32WB06xC and STM32WB07xC devices.

**Table 3. IPDs for STM32WB0xxC**

IPD	MCU package	STM32WB06xC and STM32WB07xC part number
MLPF-NRG-01D3	VFQFPN32, VFQFPN48	STM32WB06KCV, STM32WB06CCV STM32WB07KCV, STM32WB07CCV
	WLCSP49	STM32WB06CCF, STM32WB07CCF

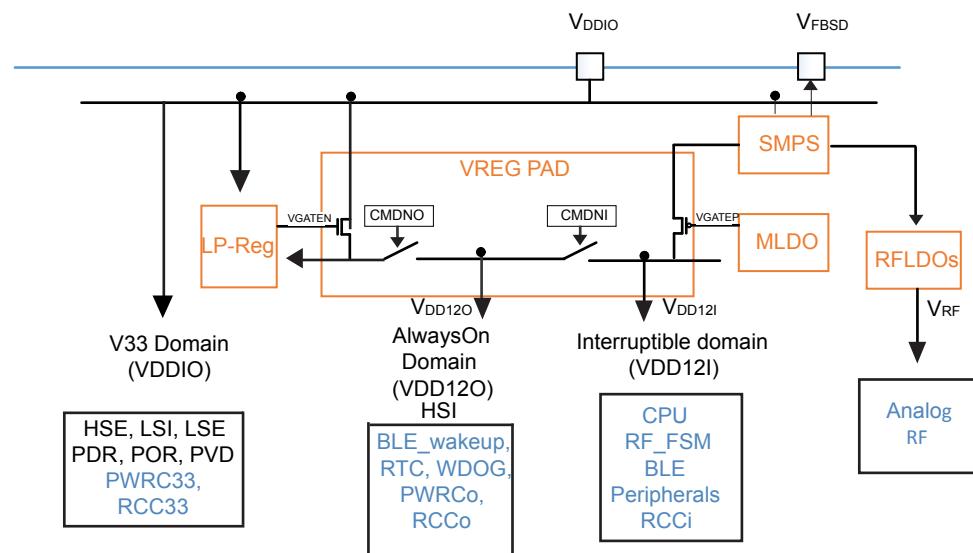
## 3.7 Power supply management

### 3.7.1 Power supply schemes

The STM32WB0xxC embeds three power domains:

- VDD33 (VDDIO or VDD):
  - the voltage range is between 1.7 V and 3.6 V
  - it supplies a part of the I/O ring, the embedded regulators and the system analog IPs as power management block and embedded oscillators
- VDD12o:
  - always-on digital power domain
  - this domain is generally supplied at 1.2 V during active phase of the device
  - this domain is supplied at 1.0 V during low power mode (Deepstop)
- VDD12i:
  - interruptible digital power domain
  - this domain is generally supplied at 1.2 V during active phase of the device
  - this domain is shut down during low-power mode (Deepstop)

**Figure 3. Power supply domain overview**



### 3.7.2 Power supply supervisor

The STM32WB0xxC device embeds several power voltage monitorings:

- Power-on-reset (POR): during the power-on, the device remains in reset mode if  $V_{DDIO}$  is below a  $V_{POR}$  threshold (typically 1.65 V)
- Power-down-reset (PDR): during power-down, the PDR puts the device under reset when the supply voltage ( $V_{DD}$ ) drops below the VPDR threshold (around 20 mV below  $V_{POR}$ ). The PDR feature is always enabled
- Programmable voltage detector (PVD): can be used to monitor the  $V_{DDIO}$  (against a programmed threshold) or an external analog input signal. When the feature is enabled and the PVD measures a voltage below the comparator, an interrupt is generated (if unmasked)

### 3.7.3

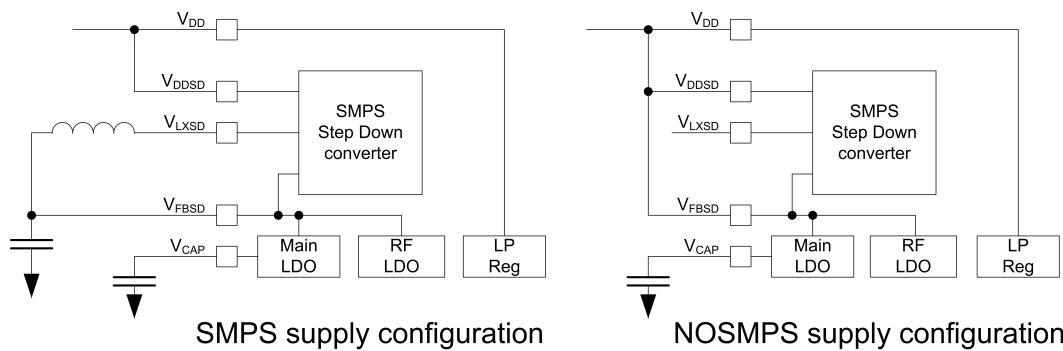
#### SMPS step-down regulator

The device integrates a step-down converter to improve low-power performance when the  $V_{DD}$  voltage is high enough. The SMPS output voltage can be programmed from 1.2 V to 1.90 V. It is internally clocked at 4 MHz or 8 MHz.

The device can be operated without the SMPS by just wiring its output to  $V_{DD}$ . This is the case for applications where the voltage is low, or where the power consumption is not critical.

Except for the configuration SMPS OFF, an L/C BOM must be present on the board and connected to the VFBSD pad.

**Figure 4. Power supply configuration**



### 3.7.4

#### Linear voltage regulators

The digital power supplies are provided by different regulators:

- The main LDO (MLDO):
    - it provides 1.2 V from a 1.4-3.3 V input voltage
    - it supplies both VDD12i and VDD12o when the device is active
    - it is disabled during the low power mode (Deepstop)
  - Low power LDO (LPREG):
    - it stays enabled during both active and low power phases
    - it provides 1.0 V voltage
    - it is not connected to the digital domain when the device is active
    - it is connected to the VDD12o domain during low power mode (Deepstop)
  - A dedicated LDO (RFLDO) to provide a 1.2 V to the analog RF block
- An embedded SMPS step-down converter is available (inserted between the external power and the LDOs).

### 3.8

#### Low-power modes

Several operating modes are defined for the STM32WB0xxC:

- Run mode
- Deepstop mode
- Shutdown mode

**Table 4. Relationship between the low power modes and functional blocks**

Mode	Shutdown	Deepstop	Idle	Run
CPU	OFF	OFF	OFF	ON
Flash	OFF	OFF	ON	ON
RAM	OFF	ON/OFF granularity 16 Kbytes	ON/OFF	ON/OFF
Radio	OFF	OFF	ON/OFF	ON/OFF
Supply system	OFF	OFF	ON (DC-DC ON/OFF)	ON (DC-DC ON/OFF)
Register retention	OFF	ON	ON	ON

Mode	Shutdown	Deepstop	Idle	Run
HS clock	OFF	OFF	ON	ON
LS clock	OFF	ON/OFF	ON	ON
Peripherals	OFF	OFF	ON/OFF	ON/OFF
Wake-on RTC	OFF	ON/OFF	ON/OFF	NA
Wake-on GPIOs	OFF	ON/OFF	ON/OFF	NA
Wake-on reset pin	ON	ON	ON	NA

### 3.8.1

#### Run mode

In Run mode the STM32WB0xxC is fully operational:

- All interfaces are active
- The internal power supplies are active
- The system clock and the bus clock are running
- The CPU core and the radio can be used

The power consumption may be reduced by gating the clock of the unused peripherals.

### 3.8.2

#### Deepstop mode

The Deepstop is the only low power mode of the STM32WB0xxC allowing the restart from a saved context environment and the application at wakeup to go on running.

The conditions to enter the Deepstop mode are:

- The radio is sleeping (no radio activity)
- The CPU is sleeping (WFI with SLEEPDEEP bit activated)
- No unmasked wakeup sources are active
- The low power mode selection (LPMS) bit of the power controller unit is 0 (default)

In Deepstop mode:

- The system and the bus clocks are stopped
- Only the essential digital power domain is ON and supplied at 1.0 V
- The bank RAM0 is kept in retention
- The other banks of RAM can be in retention or not, depending on the software configuration
- The low speed clock can be running or stopped, depending on the software configuration:
  - ON or OFF
  - Sourced by LSE or by LSI
- The RTC and the IWDG stay active, if enabled and the low speed clock is ON
- The I/Os pull-up and pull-down can be controlled during Deepstop mode, depending on the software configuration
- The radio wakeup block, including its timer, stays active (if enabled and the low speed clock is ON)
- Eight I/Os (PA4/ PA5/ PA6/ PA7/ PA8/ PA9/ PA10/ PA11) can be in output driving:
  - A static low or high level
  - The low speed clock
  - The RTC output

Possible wakeup sources are:

- The radio block is able to generate two events to wake up the system through its embedded wakeup timer running on a low speed clock:
  - Radio wakeup time is reached
  - CPU host wakeup time is reached
- The RTC can generate a wakeup event
- The IWDG can generate a reset event
- Up to 28 GPIOs are able to wake up the system (PA0 to PA15 and PB0 to PB11)

At the wakeup, all the hardware resources located in the digital power domain that are OFF during the Deepstop mode, are reset. The CPU reboots. The wakeup reason is visible in the register of the power controller.

### 3.8.3

#### Shutdown mode

The Shutdown mode is the least power-consuming mode.

The conditions to enter Shutdown mode are the same conditions needed to enter Deepstop mode except that the LPMS bit of the power controller unit is 1.

In Shutdown mode, the STM32WB0xxC is in ultralow power consumption: all voltage regulators, clocks, and the RF interface are not powered. The STM32WB0xxC can enter shutdown mode by internal software sequence. The only way to exit Shutdown mode is by asserting and deasserting the RSTN pin.

In shutdown mode:

- The system is powered down as both the regulators are OFF.
- The VDDIO power domain is ON.
- All the clocks are OFF, LSI, and LSE are OFF.
- The I/Os pull-up and pull-down can be controlled during Shutdown mode, depending on the software configuration.
- The only wakeup source is a low pulse on the RSTN pin.

The exit from Shutdown is similar to a POR startup. The PDR feature can be enabled or disabled during Shutdown.

## 3.9

### Peripheral interconnect matrix

#### 3.9.1

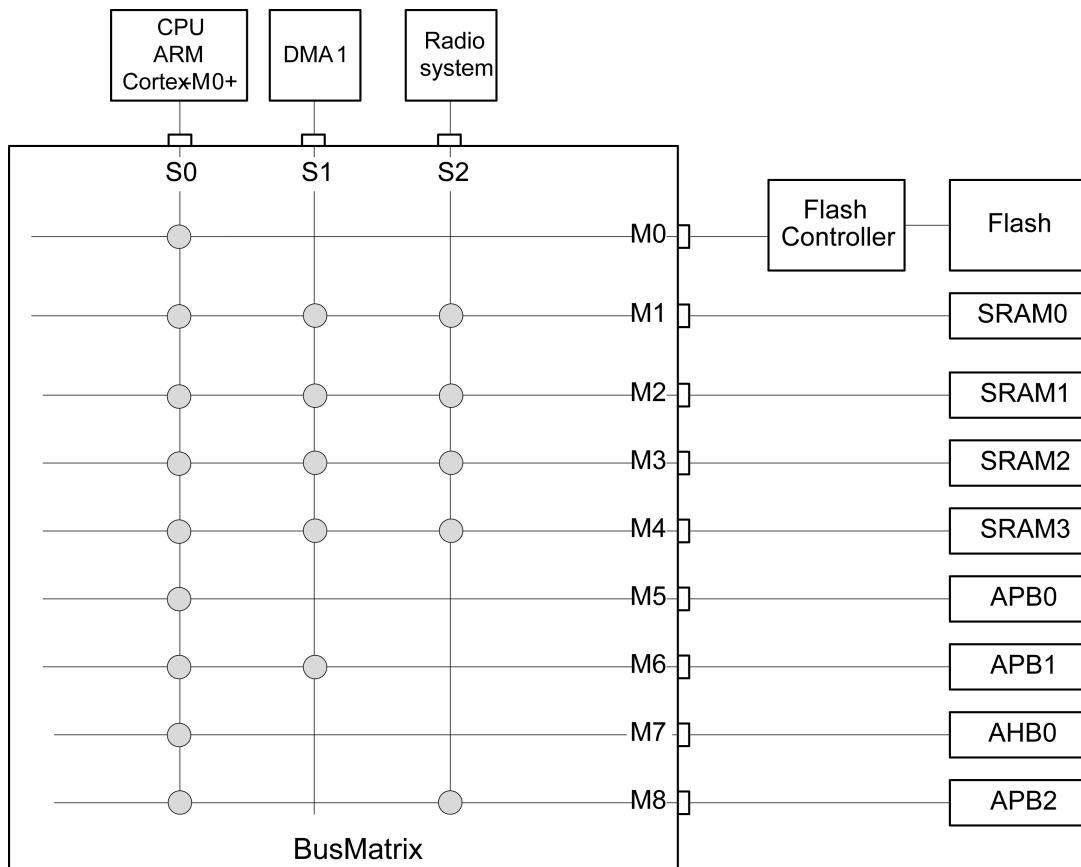
#### System architecture

The main system consists of 32-bit multilayer AHB bus matrix that interconnects:

- Three masters:
  - CPU (Cortex®-M0+) core S-bus
  - DMA1
  - Radio system
- Nine slaves:
  - Internal Flash memory on CPU (Cortex®-M0+) S bus
  - Internal SRAM0 (16 kB)
  - Internal SRAM1 (16 kB)
  - Internal SRAM2 (16 kB)
  - Internal SRAM3 (16 kB)
  - APB0 peripherals (through an AHB to APB bridge)
  - APB1 peripherals (through an AHB to APB bridge)
  - AHB0 peripherals
  - AHBRF including AHB to APB bridge and radio peripherals (connected to APB2)

The bus matrix provides access from a master to a slave, enabling concurrent access and efficient operation even when several high-speed peripherals work simultaneously.

Figure 5. Bus matrix



## 3.10 Reset and clock controller (RCC)

### 3.10.1 Reset management

The STM32WB0xxC offers two different resets:

- The PORESETn: this reset is provided by the low power management unit (LPMU) analog block and corresponds to a POR or PDR root cause. It is linked to power voltage ramp-up or ramp-down. This reset impacts all resources of the STM32WB0xxC. The exit from Shutdown mode is equivalent to a POR and thus generates a PORESETn. The PORESETn signal is active when the power supply of the device is below a threshold value or when the regulator does not provide the target voltage.

- The PADRESETn (system reset): this reset is built through several sources:
    - PORSETn
    - Reset due to the watchdog  
The STM32WB0xxC device embeds a watchdog timer, which may be used to recover from software crashes
    - Reset due to CPU lockup  
The Cortex®-M0+ generates a lockup to indicate the core is in the lock-up state resulting from an unrecoverable exception. The lock-up reset is masked if a debugger is connected to the Cortex®-M0+
    - Software system reset  
The system reset request is generated by the debug circuitry of the Cortex®-M0+. The debugger sets the SYSRESETREQ bit of the application interrupt and reset control register (AIRCR). This system reset request through the AIRCR can also be done by the embedded software (into the hard fault handler for instance)
    - Reset from the RSTN external pin  
The RSTN pin toggles to inform that a reset has occurred
- This PADRESETn resets all resources of the STM32WB0xxC, except:
- Debug features
  - Flash memory controller key management
  - RTC timer
  - Power controller unit
  - Part of the RCC registers

The pulse generator guarantees a minimum reset pulse duration of 20 µs for each internal reset source. In case of reset from the RSTN external pad, the reset pulse is generated when the pad is asserted low.

### 3.10.2 Clock management

Three different clock sources may be used to drive the system clock of the STM32WB0xxC:

- HSI: high speed internal 64 MHz RC oscillator
- PLL64M: 64 MHz PLL clock
- HSE: high speed 32 MHz external crystal

The STM32WB0xxC also has a low speed clock tree used by some timers in the radio, RTC, and IWDG.

Four different clock sources can be used for this low speed clock tree:

- Low speed internal (LSI): low speed and low drift internal RC with a fixed frequency between 24 kHz and 49 kHz depending on the sample
- Low speed external (LSE) from:
  - An external crystal 32.768 kHz
  - A single-ended 32.738 kHz input signal
- A 32 kHz clock (CLK\_16 MHz/512 in [Figure 6. Clock tree](#)) obtained by dividing HSI or HSE. In this case, the slow clock is not available in Deepstop low power mode
- LSI\_LPMU: 32 kHz clock used by the low power management unit (LPMU) analog block.

By default, after a system reset, all low-speed sources are OFF.

Both the activation and the selection of the slow clock are relevant during the Deepstop mode and at wakeup as the slow clock generates a clock for the timers involved in wakeup event generation.

The HSI and the PLL64M clocks are provided by the same analog block called RC64MPPLL. The 64 MHz clock output by this block can be:

- A nonaccurate clock when no external XO provides an input clock to this block (HSI)
- An accurate clock when the external XO provides the 32 MHz and once its internal PLL is locked (PLL64M)

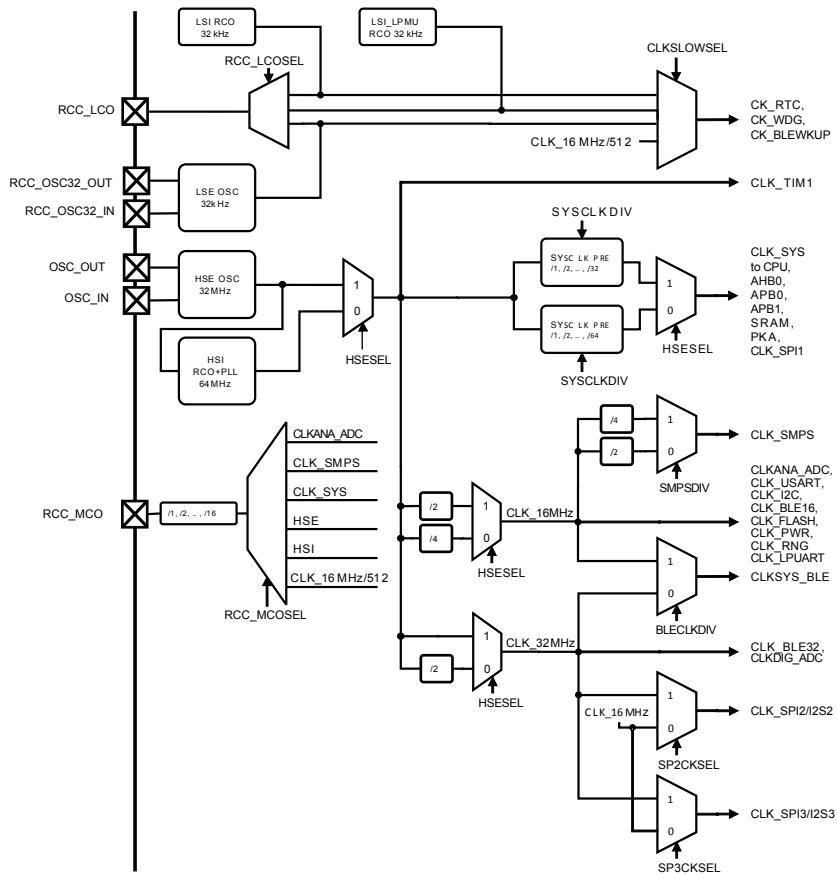
This fast clock source is used to generate all the fast clocks of the device through dividers. After reset, the CLK\_SYS is divided by four to provide a 16 MHz to the whole system (CPU, DMA, memories, and peripherals).

This fast clock source is also used to generate several internal fast clocks in the system:

- Always 32 MHz requested by a few peripherals like the radio

- Always 16 MHz requested by a few peripherals like serial interfaces (to maintain fixed the baud rate while the system clock is switching from one frequency to another) or like the flash memory controller and radio (to have a fixed reference clock to manage delays)

**Figure 6. Clock tree**



DT58107V2

It is possible to output some internal clocks on external pads:

- The low speed clocks can be output on the RCC\_LCO I/O
- The high speed clocks can be output on the RCC\_MCO I/O

This is possible by programming the associated I/O in the correct alternate function.

Most of the peripherals only use the system clock except:

- I<sup>2</sup>C, USART, LPUART: they always use an a16 MHz clock to have a fixed reference clock for baud rate management. The goal is to allow the CPU to boost or slow down the system clock (depending on ongoing activities) without impacting a potential ongoing serial interface transfer on external I/Os
- SPI: when the I2S mode is used, the baud rate is always managed through the 16 MHz or 32 MHz clock. When modes other than the I2S run, the baud rate is managed by the system clock. This implies that its baud rate is impacted by dynamic system clock frequency changes
- RNG: in parallel to the system clock, the RNG always uses a 16 MHz clock to generate at a constant frequency the random number whatever the system clock frequency
- Flash memory controller: in parallel to the system clock, the flash memory controller always uses a 16 MHz clock to generate specific delays required by the flash memory during programming and erase operations for example
- PKA: in parallel to the system clock, the PKA uses a clock at half of the system clock frequency

- Radio: it does not directly use the system clock for its APB/AHB interfaces, but the system clock with a potential divider (1 or 2 or 4). In parallel, the radio always uses 16 MHz and always 32 MHz for modulator, demodulator and to have a fixed reference clock to manage specific delays
- ADC: in parallel to the system clock, ADC uses a 64 MHz prescaled clock running at 16 MHz

### 3.11

## General purpose inputs/outputs (GPIO)

Each of the GPIO pins can be configured by software as output (push-pull or open-drain), as input (with or without pull-up or pull-down) or as peripheral alternate function. Most of the GPIO pins are shared with digital or analog alternate functions. Fast I/O toggling can be achieved thanks to their mapping on the AHB0 bus.

The I/Os alternate function configuration can be locked if needed following a specific sequence in order to avoid spurious writing to the I/Os registers.

#### 3.11.1

### Tx and Rx event alert

The STM32WB0xxC is provided with the RADIO\_TX\_SEQUENCE and RADIO\_RX\_SEQUENCE signals which alert, respectively, transmission and reception activities.

A signal can be enabled for Tx and Rx on two pins, through alternate functions:

- RADIO\_TX\_SEQUENCE is available on PA10 (AF2) or PB15 (AF1).
- RADIO\_RX\_SEQUENCE is available on PA8 (AF2) or PA11 (AF2).

The signal is high when the radio is in Tx (or Rx), low otherwise.

The signals can be used to control external antenna switching and support coexistence with other wireless technologies.

### 3.12 Direct memory access (DMA)

The DMA is used in order to provide high-speed data transfer between peripherals and memory as well as memory-to-memory. Data can be quickly moved by DMA without any CPU actions. In this manner, CPU resources are free for other operations.

The DMA controller has eight channels in total. Each has an arbiter to handle the priority among DMA requests.

DMA main features are:

- Eight independently configurable channels (requests)
- Each of the eight channels is connected to dedicated hardware DMA requests, software trigger is also supported on each channel. This configuration is done by software
- Priorities among requests from channels of DMA are software programmable (four levels consisting of very high, high, medium, low) or hardware in case of equality (request 1 has priority over request 2, and so on)
- Independent source and destination transfer size (byte, half word, word), emulating packing and unpacking. Source/destination addresses must be aligned on the data size
- Support for circular buffer management
- Three event flags (DMA half transfer, DMA transfer complete and DMA transfer error) logically ORed together in a single interrupt request for each channel
- Memory-to-memory transfer (RAM only)
- Peripheral-to-memory and memory-to-peripheral, and peripheral-to-peripheral transfers
- Access to SRAMs and APB1 peripherals as source and destination
- Programmable number of data to be transferred: up to 65536

### 3.13 Interrupts and events

#### 3.13.1 Nested vectored interrupt controller (NVIC)

The interrupts are handled by the Cortex®-M0+ nested vector interrupt controller (NVIC). NVIC controls specific Cortex®-M0+ interrupts as well as the STM32WB0xxC peripheral interrupts.

The NVIC benefits are the following:

- Nested vectored interrupt controller that is an integral part of the Arm® Cortex®-M0+
- A tightly coupled interrupt controller provides low interrupt latency
- Control system exceptions and peripheral interrupts
- NVIC supports 32 vectored interrupts
- Four programmable interrupt priority levels with hardware priority level masking
- Software interrupt generation using the Arm® exceptions SVCCall and PendSV
- Support for NMI
- Arm® Cortex® M0+ vector table offset register VTOR implemented

NVIC hardware block provides flexible interrupt management features with minimal interrupt latency.

### 3.14 Analog digital converter (ADC)

The STM32WB0xxC embeds a 12-bit ADC. The ADC consists of a 12-bit successive approximation analog-to-digital converter (SAR) with 2 x 8 multiplexed channels allowing measurements of up to eight external sources and up to two internal sources.

The ADC main features are:

- Conversion frequency is up to 1 Msps
- Three input voltage ranges are supported (0 - 1.2 V, 0 - 2.4 V, 0 - 3.6 V)
- Up to eight analog single-ended channels or four analog differential inputs or a mix of both
- Temperature sensor conversion
- Battery level conversion up to 3.6 V
- ADC continuous or single mode conversion is possible
- ADC down-sampler for multi-purpose applications to improve analog performance while off-loading the CPU (ratio adjustable from 1 to 128)
- A watchdog feature to inform when data is outside thresholds

- DMA capability
- Interrupt sources with flags.

### 3.14.1 Digital MEMS microphone interface

The digital MEMS microphone interface aims to interconnect with an external digital MEMS microphone. The STM32WB0xxC can configure two GPIOs as a PDM interface. The PDM\_CLK provides the clock output signal, programmable in frequency, to the microphone, while the PDM\_DATA receives the PDM output data from the microphone. The decimation filter and the digital control resources are used to handle the PDM data stream.

### 3.14.2 Analog microphone interface

The analog microphone interface is dedicated to the analog microphone signal. The input audio signal is amplified with a programmable gain amplifier (PGA) from 0 dB to 30 dB, then the data stream is sampled by ADC and processed through the decimation filter.

### 3.14.3 Temperature sensor

The temperature sensor (TS) generates a voltage that varies linearly with temperature. The temperature sensor is internally connected to the ADC input channel, which is used to convert the sensor output voltage into a digital value.

To improve the accuracy of the temperature sensor measurement, each device is individually factory-calibrated by ST. The temperature sensor factory calibration data are stored by ST in the system memory area, accessible in read-only mode.

## 3.15 True random number generator (RNG)

An RNG, or random number generator, is based on continuous analog noise and provides a 16-bit value to the host upon being read. The minimum period is 1.25 µs, which corresponds to 20 RNG clock cycles between two consecutive random numbers.

## 3.16 Timers and watchdog

The STM32WB0xxC includes one advanced 16-bit timer, one watchdog timer, and a SysTick timer.

### 3.16.1 Advanced control timer (TIM1)

The advanced-control timer can be considered as a three-phase PWM multiplexed on six channels. The six channels have complementary PWM outputs with programmable inserted dead-times.

They can also be used as general-purpose timers for:

- Input capture (except channels 5 and 6)
- Output compare
- PWM generation (edge and center-aligned mode)
- One-pulse mode output

### 3.16.2 Independent watchdog (IWDG)

The independent watchdog is based on a 12-bit downcounter and 8-bit prescaler. It is clocked from the LS clock and it can operate in Deepstop mode. It can also be used as a watchdog to reset the device when a problem occurs.

### 3.16.3 SysTick timer

This timer is dedicated to real-time operating systems, but could also be used as a standard down counter. Its features:

- A 24-bit down counter
- Autoreload capability
- Maskable system interrupt generation when the counter reaches 0

## 3.17 Real-time clock (RTC), tamper and backup registers

### 3.17.1 Real-time clock (RTC)

The RTC is an independent BCD timer/counter. The RTC provides a time of day/clock/calendar with programmable alarm interrupt. RTC includes also a periodic programmable wakeup flag with interrupt capability. The RTC provides an automatic wakeup to manage all low power modes.

Two 32-bit registers contain seconds, minutes, hours (12- or 24-hour format), day (day of week), date (day of month), month, and year, expressed in binary coded decimal format (BCD). The sub-second value is also available in binary format. Compensations for 28-, 29- (leap year), 30-, and 31-day months are performed automatically. Daylight saving time compensation can also be performed. Additional 32-bit registers contain the programmable alarm sub seconds, seconds, minutes, hours, day, and date.

A digital calibration circuit with 0.95 ppm resolution is available to compensate for quartz crystal inaccuracy. After power-on reset, all RTC registers are protected against possible parasitic write accesses. As long as the supply voltage remains in the operating range, the RTC never stops, regardless of the device status (Run mode, low power mode or under system reset). The RTC counter does not freeze when CPU is halted by a debugger.

## 3.18 Inter-integrated circuit interface (I<sup>2</sup>C)

The STM32WB0xxC embeds two I<sup>2</sup>Cs. The I<sup>2</sup>C bus interface handles communications between the microcontroller and the serial I<sup>2</sup>C bus. It controls all I<sup>2</sup>C bus-specific sequencing, protocol, arbitration, and timing. The I<sup>2</sup>C peripheral supports:

- I<sup>2</sup>C bus specification and user manual rev. 5 compatibilities:
  - Target and controller modes
  - Multicontroller capability
  - Standard mode (Sm), with a bitrate up to 100 Kbit/s
  - Fast mode (Fm), with a bitrate up to 400 Kbit/s
  - Fast mode plus (Fm+), with a bitrate up to 1 Mbit/s and 20 mA output driver I/Os
  - 7-bit and 10-bit addressing mode
  - Multiple 7-bit target addresses (two addresses, 1 with configurable mask)
  - All 7-bit address acknowledge mode
  - General call
  - Programmable setup and hold times
  - Easy to use event management
  - Optional clock stretching
  - Software reset
- System management bus (SMBus) specification rev 2.0 compatibility:
  - Hardware PEC (Packet Error Checking) generation and verification with ACK control
  - Address resolution protocol (ARP) support
  - Host and device support
  - SMBus alert
  - Timeouts and idle condition detection
- Power system management protocol (PMBus™) specification Rev. 1.1 compatibility
- Independent clock: a choice of independent clock sources allowing the I<sup>2</sup>C communication speed to be independent from the PCLK reprogramming
- Programmable analog and digital noise filters
- 1-byte buffer with DMA capability

## 3.19 Universal synchronous/asynchronous receiver transmitter (USART/UART)

USART offers flexible full-duplex data exchange with external equipment requiring an industry standard NRZ asynchronous serial data format. USART is able to communicate with a speed up to 2 Mbit/s. Furthermore, USART is able to detect and automatically set its own baud rate, based on the reception of a single character.

The USART peripheral supports:

- Synchronous one-way communication
- Half-duplex single wire communication
- Local interconnection network (LIN) master/slave capability
- Smart card mode, ISO 7816 compliant protocol
- IrDA (infrared data association) SIR ENDEC specifications
- Modem operations (CTS/RTS)
- RS485 driver enable
- Multiprocessor communications
- SPI-like communication capability

High speed data communication is possible by using DMA (direct memory access) for multibuffer configuration.

### 3.19.1

#### Embedded UART bootloader

The STM32WB0xxC has a preprogrammed bootloader supporting the UART protocol with automatic baud rate detection. The main features of the embedded bootloader are:

- Auto baud rate detection up to 1 Mbps
- Flash mass erase, section erase
- Flash programming
- Flash readout protection enable/disable

The preprogrammed bootloader is an application, which is stored in the STM32WB0xxC internal ROM at manufacturing time by STMicroelectronics. This application allows upgrading the flash device with a user application using a serial communication channel (UART).

The bootloader is activated by hardware by forcing PA10 high during hardware reset, otherwise, application residing in flash is launched.

### 3.20

#### LPUART

LPUART is a UART which allows bidirectional UART communications. It supports half-duplex single wire communications and modem operations (CTS/RTS). It also supports multiprocessor communications. DMA (direct memory access) can be used for data transmission/reception.

### 3.21

#### Serial peripheral interface (SPI)

The STM32WB0xxC has three SPI interfaces (SPI1, SPI2, SPI3) allowing communication up to 32 Mbit/s in both controller and target modes. The SPI peripheral supports:

- Controller or target operation
- Multimaster support
- Full-duplex synchronous transfers on three lines
- Half-duplex synchronous transfer on two lines (with bidirectional data line)
- Simplex synchronous transfers on two lines (with unidirectional data line)
- Serial communication with external devices
- NSS management by hardware or software for both controller and target: dynamic change of controller/target operations
- SPI Motorola support
- SPI TI mode support
- Hardware CRC features for reliable communication

All SPI interfaces can be served by the DMA controller.

### 3.21.1

#### Inter-IC sound (I2S)

The STM32WB0xxC SPI interfaces: SPI2 and SPI3 support the I2S protocol. The I2S interface can operate in target or controller mode with half-duplex communication. It can address four different audio standards:

- Philips I2S standard
- MSB-justified standards (left-justified)
- LSB-justified standards (right-justified)

- Phase-change memory standard.
- The I2S interfaces DMA capability for transmission and reception.

## 3.22 Development support

### 3.22.1 Serial wire debug port

The STM32WB0xxC embeds an Arm SWD interface that allows interactive debugging and programming of the device. The interface is composed of only two pins: DEBUG\_SWDIO and DEBUG\_SWCLK. The enhanced debugging features for developers allow up to four breakpoints and up to two watchpoints.

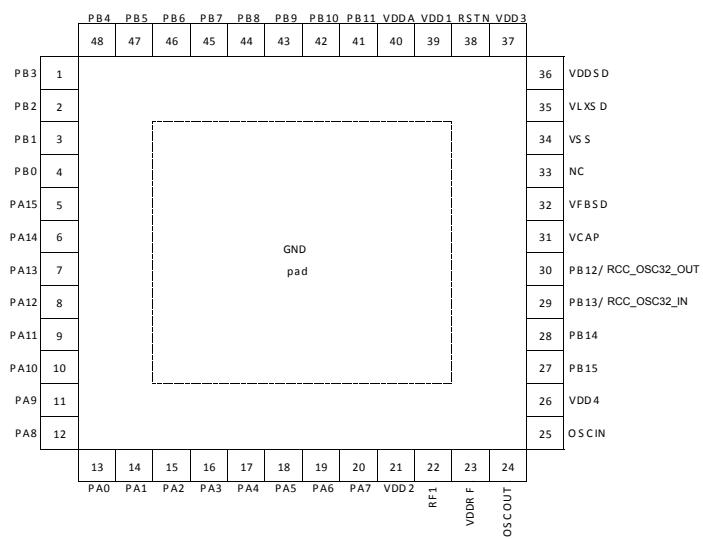
## 4 Pinouts/ballouts, pin description, and alternate functions

### 4.1 Pinout/ballout schematics

The STM32WB0xxC comes in three package versions: VFQFPN48 offering 32 GPIOs, WLCSP49 offering 30 GPIOs and VFQFPN32 offering 20 GPIOs.

**Figure 7. VFQFPN48 pinout**

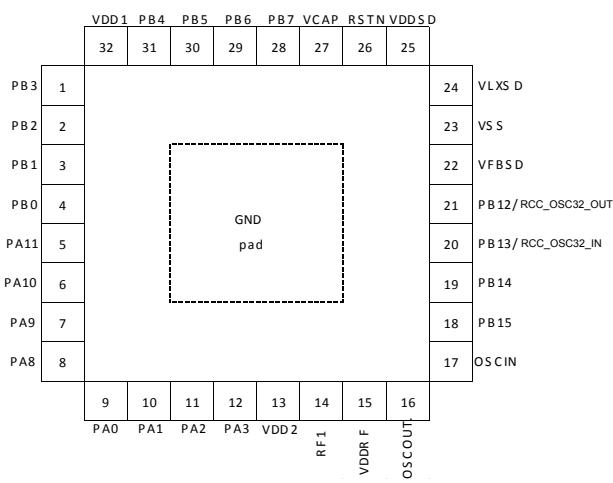
Package top view



DT58108V2

**Figure 8. VFQFPN32 pinout**

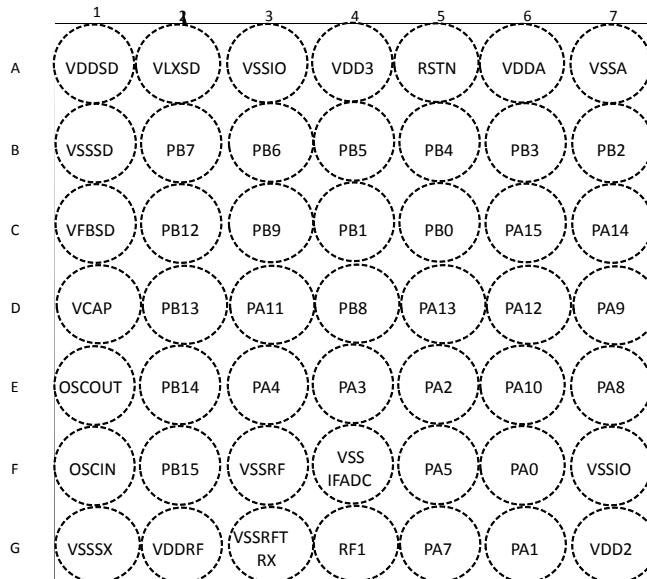
Package top view



DT58109V2

**Figure 9. WLCSP49 pinout**

Package top view



DT58110V1

## 4.2 Pin description

**Table 5. Legend/abbreviations used in the pinout table**

Name	Abbreviation	Definition
Pin name		Unless otherwise specified in brackets below the pin name, the pin function during and after reset is the same as the actual pin name.
Pin type	A	Analog-only input
	I	Input-only pin
	I/O	Input/output pin
	O	Output-only pin
	S	Supply pin
I/O structure	DDR	DDR 1.5 V or 1.2 V I/O for DDR3, DDR3L, LPDDR2/LPDDR3, DDR4, and LPDDR4 interfaces
	DSI	1.2 V I/O for DSI interface
	FT	5 V-tolerant I/O
	FTP	5 V-tolerant I/O with fixed pull-down
	FTPD	5 V-tolerant I/O with fixed programmable pull-down
	FTU	5 V-tolerant I/O with fixed pull-up
	RF	RF I/O
	TC	3.6 V-capable I/O with ESS diode connected to $V_{DD}$
	TT	3.6 V-tolerant I/O
	TTa	3.6 V-tolerant I/O with internal clamping to $V_{DDA}$
	B	Dedicated BOOT0 pin
	POR	External power on reset pin with embedded weak pull-up resistor, powered from $V_{DDA}$
	RST	Bidirectional reset pin with embedded weak pull-up resistor
<b>Options for TT and FT I/Os<sup>(1)</sup></b>		
	_a	I/O with analog switch function supplied by $V_{DDA}$
	_c	USB Type-C® power delivery capable I/O
	_d	USB Type-C® power delivery dead battery function I/O
	_e	I/O with switchable diode to $V_{DD}$
	_f	I2C Fm+ capable I/O
	_h	High-speed low-voltage I/O
	_l	I/O with LCD function supplied by $V_{LCD}$

Name	Abbreviation	Definition
I/O structure	_p	I/O with differential clock capability CLKP/CLKN
	_s	I/O supplied only by V <sub>DDIO2</sub>
	_t	Tamper I/O
	_u	I/O with USB function, supplied by V <sub>DDUSB</sub>
	_v	Very high-speed I/O
Notes	Unless otherwise specified by a note, all I/Os are set as floating inputs during and after reset.	
Pin functions	Alternate functions	Functions selected through GPIOx_AFR registers
	Additional functions	Functions directly selected/enabled through peripheral registers

1. The related I/O structures in the table below are a concatenation of various options. Examples: FT\_hat, FT\_fs, FT\_u, TT\_a.







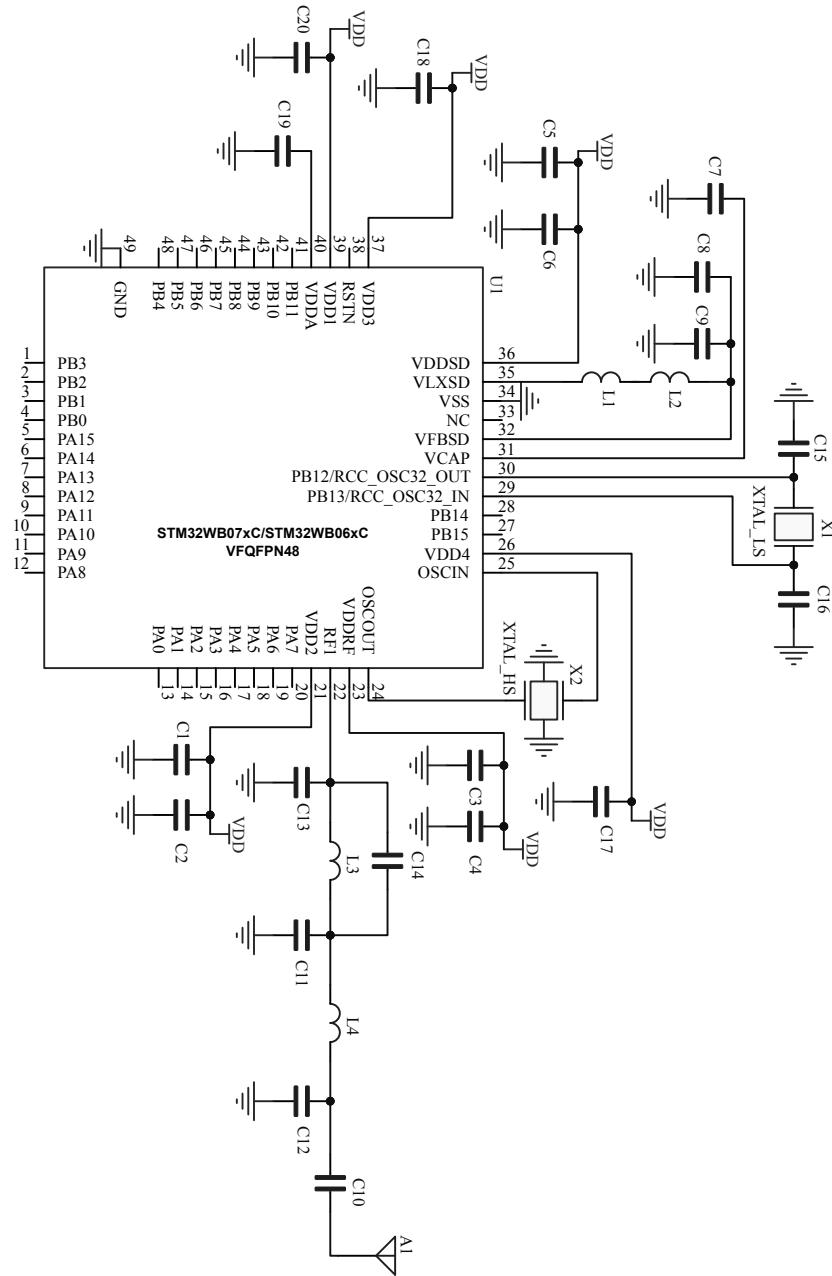


Port		AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7
		SPI1/I2C2 USART/LPUART	PDM/SYS_AF/I2C2 LPUART/SPI2/I2S2	SPI2/I2C1/PDM TIM1/SYS_AF/I2S2	TIM1/PDM LPUART	TIM1	-	-	USART
Port B	PB14	SPI1_MOSI	I2C2_SDA	TIM1_ETR	TIM1_CH3N	-	-	-	USART_RX
	PB15	I2C1_SMBA	RADIO_TX_SEQUENCE	RCC_MCO	TIM1_CH4N	-	-	-	USART_TX

## 5 Application circuits

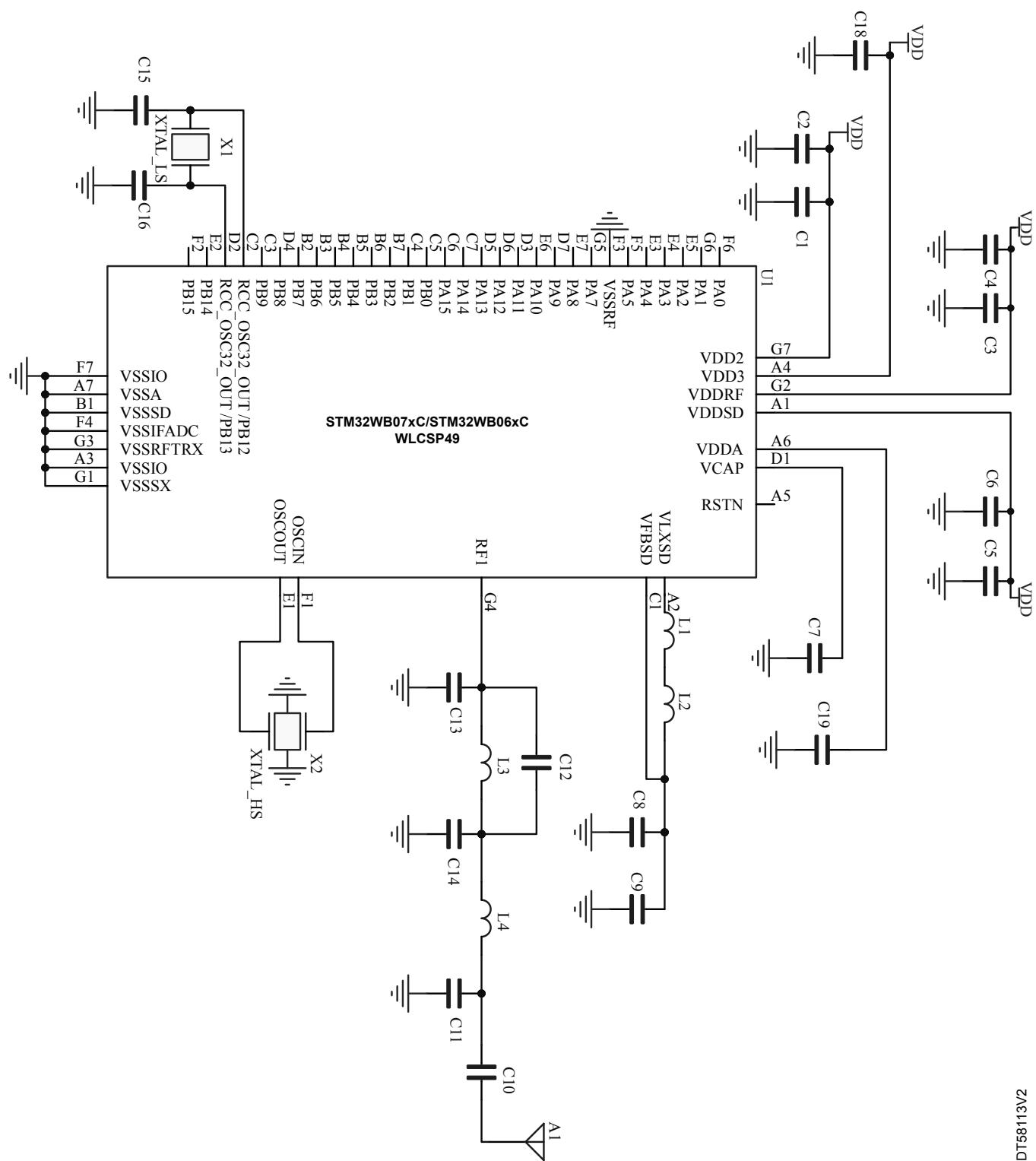
The schematics below are purely indicative.

**Figure 10. Application circuit: DC-DC converter, VFQFPN48 package**



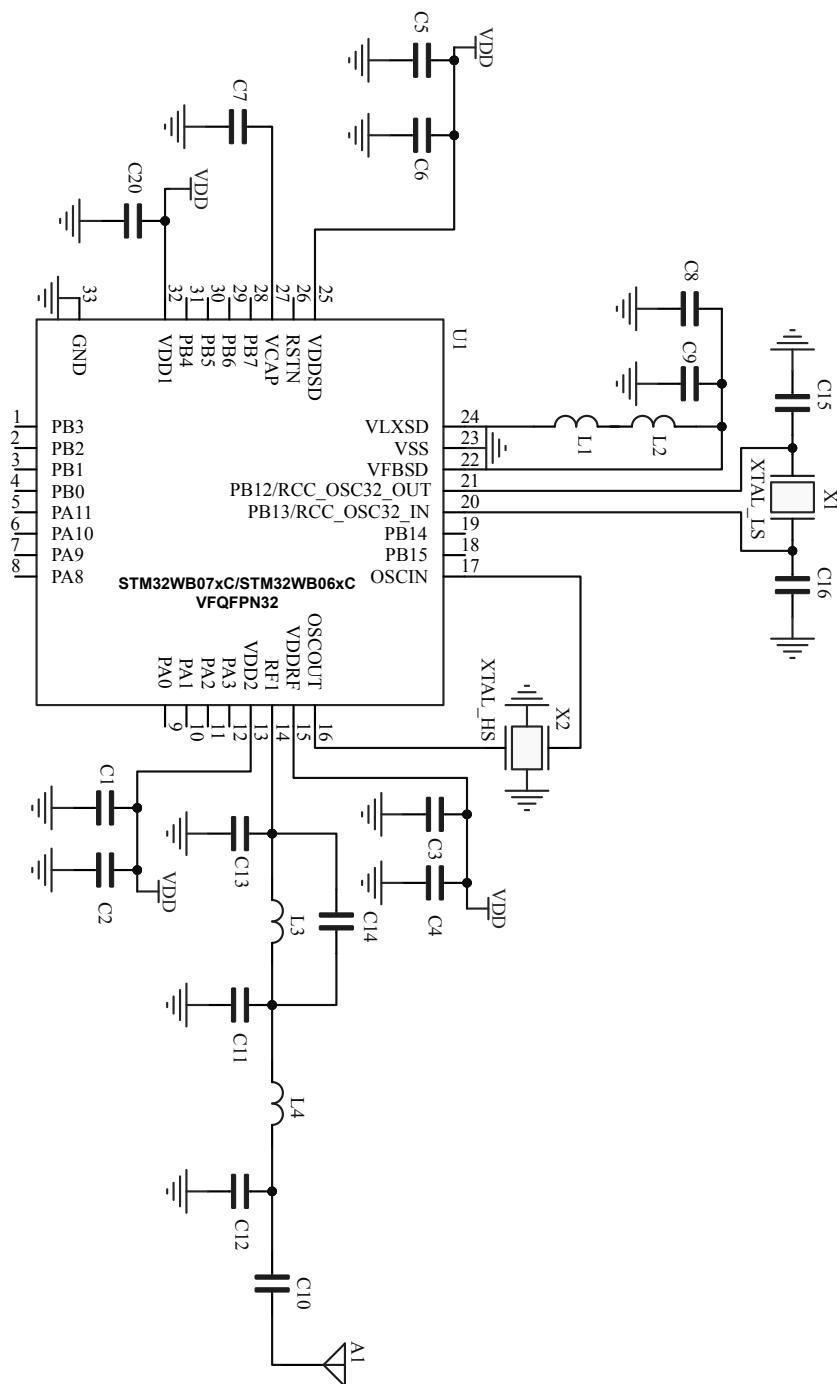
DS14676 - Rev 3

**Figure 11.** Application circuit: DC-DC converter, WLCSP49 package



DS14676 - Rev 3

**Figure 12.** Application circuit: DC-DC converter, VFQFPN32 package



D758147Z

**Table 9. Application circuit external components**

Component	Description
C1	Decoupling capacitor
C2	Decoupling capacitor
C3	Decoupling capacitor
C4	Decoupling capacitor
C5	Decoupling capacitor
C6	Decoupling capacitor
C7	Decoupling capacitor
C8	DC-DC converter output capacitor
C9	DC-DC converter output inductor
C10	DC block capacitor
C11	RF matching capacitor
C12	RF matching capacitor
C13	RF matching capacitor
C14	RF matching capacitor
C15	32 kHz crystal loading capacitor
C16	32 kHz crystal loading capacitor
C17	Decoupling capacitor
C18	Decoupling capacitor
C19	Decoupling capacitor
C20	Decoupling capacitor
L1	DC-DC converter output inductor
L2	DC-DC converter filtering inductor
L3	RF matching inductor
L4	RF matching inductor
X1	Low speed crystal
X2	High speed crystal
U1	STM32WB06xC/STM32WB07xC

**Note:** In order to make the board DC-DC OFF, the inductance L1 must be removed and the supply voltage must be applied to the VFBS pin.

## 6 Electrical characteristics

### 6.1 Parameter conditions

Unless otherwise specified, all voltages are referenced to V<sub>SS</sub>.

#### 6.1.1 Minimum and maximum values

Unless otherwise specified the minimum and maximum values are guaranteed in the worst conditions of junction temperature, supply voltage and frequencies by tests in production on 100 % of the devices with an junction temperature at T<sub>J</sub> = 25 °C and T<sub>J</sub> = T<sub>Jmax</sub> (given by the selected temperature range).

Data based on characterization results, design simulation and/or technology characteristics are indicated in the table footnotes. Based on characterization, the minimum and maximum values refer to sample tests and represent the mean value plus or minus three times the standard deviation (mean  $\pm 3\sigma$ ).

#### 6.1.2 Typical values

Unless otherwise specified, typical data are based on T<sub>J</sub> = 25 °C, V<sub>DD</sub> = 3.3 V (for the 1.62 V  $\leq$  V<sub>DD</sub>  $\leq$  3.6 V voltage range). They are given only as design guidelines and are not tested.

Typical ADC accuracy values are determined by characterization of a batch of samples from a standard diffusion lot over the full temperature range, where 95% of the devices have an error less than or equal to the value indicated (mean  $\pm 2\sigma$ ).

#### 6.1.3 Typical curves

Unless otherwise specified, all typical curves are given only as design guidelines and are not tested.

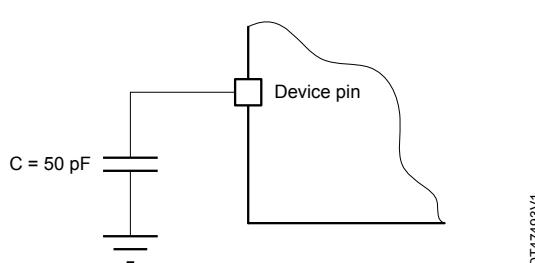
#### 6.1.4 Loading capacitor

The loading conditions used for pin parameter measurement are shown in Figure 13.

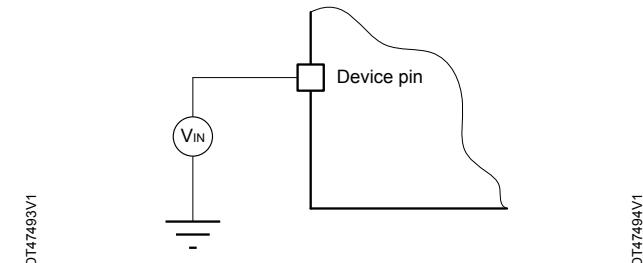
#### 6.1.5 Pin input voltage

The input voltage measurement on a pin of the device is described in Figure 14.

**Figure 13. Pin loading conditions**



**Figure 14. Pin input voltage**



## 6.2 Absolute maximum ratings

Stresses above the absolute maximum ratings listed in the tables below, may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these conditions is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

**Table 10. Voltage characteristics**

Symbol	Ratings	Min.	Max.	Unit
VDD1, VDD2, VDD3, VDD4, VDDRF, VDDSD	DC-DC converter supply voltage input and output	-0.3	+3.9	V
VCAP, VDDA	DC voltage on linear voltage regulator	-0.3	+1.32	



Symbol	Parameter	Conditions	Min.	Max.	Unit
$V_{IN}$	I/O input voltage	-	-0.3	$VDD+0.3$	V
$P_D$	Power dissipation at $T_A=105\text{ }^{\circ}\text{C}$ <sup>(1)</sup>	VFQFPN48 package	-	30	mW
		VFQFPN32 package			
$T_A$	Ambient temperature	Maximum power dissipation	-40	105	$^{\circ}\text{C}$
$T_J$	Junction temperature range	-	-40	105	-

1.  $T_A$  cannot exceed the  $T_J$  max.

### 6.3.2 Summary of main performance

**Table 14. Main performance SMPS ON**

Symbol	Parameter	Test conditions	Typ. $VDD = 1.8\text{ V}$	Typ. $VDD = 3.3\text{ V}$	Unit
$I_{CORE}$	Core current consumption	Shutdown	8	19	nA
		Deepstop, no timer, wakeup GPIO, RAM0 retained	0.44	0.46	$\mu\text{A}$
		Deepstop, no timer, wakeup GPIO, all RAM retained	0.62	0.64	
		Deepstop (32 kHz LSI), RAM0 retained	0.94	1.06	
		Deepstop (32 kHz LSI), all RAMs retained	1.12	1.24	
		Deepstop (32 kHz LSE), RAM0 retained	0.64	0.75	
		Deepstop (32 kHz LSE), all RAM retained	0.83	0.94	
		CPU in Run (64 MHz). Dhystone, clock source PLL64	-	2719	$\mu\text{A}$
		CPU in Run (32 MHz). Dhystone, clock source PLL64	-	2188	
		CPU in WFI (64 MHz), all peripherals off, clock source PLL64	-	1708	
		CPU in WFI (16 MHz), all peripherals off, clock source direct HSE	-	1092	
		Radio Rx at sensitivity level	-	3350	
		Radio Tx 0 dBm output power	-	4300	
$I_{DYNAMIC}$	Dynamic current	Computed value: (CPU 64 MHz Dhystone - CPU 32 MHz Dhystone) / 32	-	16.5	$\mu\text{A}/\text{MHz}$

**Table 15. Main performance SMPS bypassed**

Symbol	Parameter	Test conditions	Typ. VDD = 1.8 V	Typ. VDD = 3.3 V	Unit
I <sub>CORE</sub>	Core current consumption	Shutdown	8	19	nA
		Deepstop, no timer, wakeup GPIO, RAM0 retained	0.44	0.46	µA
		Deepstop, no timer, wakeup GPIO, all RAM retained	0.62	0.64	
		Deepstop (32 kHz LSI), RAM0 retained	0.94	1.06	
		Deepstop (32 kHz LSI), all RAMs retained	1.12	1.24	
		Deepstop (32 kHz LSE), RAM0 retained	0.64	0.75	
		Deepstop (32 kHz LSE), all RAM retained	0.83	0.94	
		CPU in Run (64 MHz). Dhrystone, clock source PLL64	-	4482	
		CPU in WFI (64 MHz), all peripherals off, clock source PLL64	-	2230	
		CPU in WFI (16 MHz), all peripherals off, clock source direct HSE	-	757	
		Radio Rx at sensitivity level	-	6700	
		Radio Tx 0 dBm output power	-	8900	

**Table 16.** Peripheral current consumption at VDD = 3.3 V, sysclk at 32 MHz, SMPS on

Parameter	Test conditions	Typ.	Unit
ADC	-	80	µA
DMA	-	39	
GPIOA	-	2	
GPIOB	-	2	
I2C1	-	40	
I2C2	-	39	
I2S2	Peripheral clock at 32 MHz	46	
I2S3	Peripheral clock at 32 MHz	47	
IWDG	-	11	
LPUART	-	52	
PVD	-	0.8	
PKA	-	50	
RNG	-	64	
RTC	-	14	
SPI1	-	35	
SPI2	Peripheral clock at 16 MHz	40	
SPI3	Peripheral clock at 16 MHz	42	
SysTick	-	8	
TIM1	-	248	
USART	-	81	
SYSCFG	-	33	
THSENS	-	301	
CRC	-	9	

### 6.3.3 RF general characteristics

All performance data are referred to a 50 Ω antenna connector, via reference design.







Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
RF selectivity with Bluetooth® Low Energy equal modulation on interfering signal						
C/I <sub>CO-channel</sub>	Co-channel interference $f_{RX} = f_{interference}$	Wanted signal= -67 dBm, PER < 30.8%	-	8	-	dBc
C/I <sub>2 MHz</sub>	Adjacent interference $f_{interference} = f_{RX} \pm 2 \text{ MHz}$	Wanted signal = -67 dBm, PER < 30.8%	-	-14	-	dBc
C/I <sub>4 MHz</sub>	Adjacent interference $f_{interference} = f_{RX} \pm 4 \text{ MHz}$	Wanted signal = -67 dBm, PER < 30.8%	-	-41	-	dBc
C/I <sub>6 MHz</sub>	Adjacent interference $f_{interference} = f_{RX} \pm (6+2n) \text{ MHz}$ [n = 0,1,2...]	Wanted signal = -67 dBm, PER < 30.8%	-	-45	-	dBc
C/I <sub>Image</sub>	Image frequency interference $f_{interference} = f_{image-2M}$	Wanted signal = -67 dBm, PER < 30.8%	-	-25	-	dBc
C/I <sub>Image±1 MHz</sub>	Adjacent channel-to-image frequency	Wanted signal= -67 dBm, PER < 30.8%	-	-14	-	dBc
	$f_{interference} = f_{image-2M} \pm 2 \text{ MHz}$		-			
Out of band blocking (interfering signal CW)						
C/I <sub>Block</sub>	Interfering signal frequency 30 MHz – 2000 MHz	Wanted signal= -67 dBm, PER < 30.8%, measurement resolution 10 MHz	-	5	-	dB
C/I <sub>Block</sub>	Interfering signal frequency 2003 MHz – 2399 MHz	Wanted signal= -67 dBm, PER < 30.8%, measurement resolution 3 MHz	-	-5	-	dB
C/I <sub>Block</sub>	Interfering signal frequency 2484 MHz – 2997 MHz	Wanted signal= -67 dBm, PER < 30.8%, measurement resolution 3 MHz	-	-5	-	dB
C/I <sub>Block</sub>	Interfering signal frequency 3000 MHz – 12.75 GHz	Wanted signal= -67 dBm, PER < 30.8%, measurement resolution 25 MHz	-	10	-	dB
Intermodulation characteristics (CW signal at $f_1$ , Bluetooth® Low Energy interfering signal at $f_2$ )						
P_IM(6)	Input power of IM interferer at 6 and 12 MHz distance from the wanted signal	Wanted signal= -64 dBm, PER < 30.8%	-	-27	-	dBm
P_IM(-6)	Input power of IM interferer at -6 and -12 MHz distance from the wanted signal	Wanted signal= -64 dBm, PER < 30.8%	-	-30	-	dBm
P_IM(8)	Input power of IM interferer at ±8 and ±16 MHz distance from the wanted signal	Wanted signal= -64 dBm, PER < 30.8%	-	-30	-	dBm
P_IM(10)	Input power of IM interferer at ±10 and ±20 MHz distance from the wanted signal	Wanted signal= -64 dBm, PER < 30.8%	-	-28	-	dBm







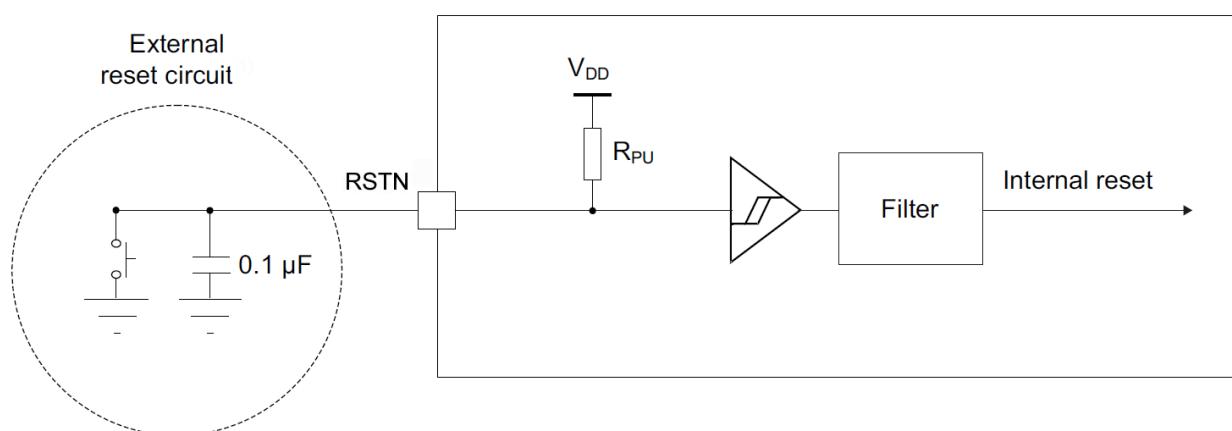






**Table 38. RSTN pin characteristics**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{IL(RSTN)}$	RSTN input low level voltage	-	-	-	$0.3 \times VDD$	V
$V_{IH(RSTN)}$	RSTN input high level voltage	-	$0.7 \times VDD$	-	-	
$V_{hys(RSTN)}$	RSTN Schmitt trigger voltage hysteresis	-	-	200	-	mV
RPU	Weak pull-up equivalent resistor	VIN=GND	25	40	55	kΩ

**Figure 15. Recommended RSTN pin protection****Note:**

The external reset circuit protects the device against parasitic resets.

The user must ensure that the level on the RSTN pin can go below the  $V_{IL(RSTN)}$  max. level specified in the table, otherwise the reset is not considered by the device. The external capacitor on RSTN must be placed as close as possible to the device.

### **6.3.16 ADC characteristics**

**Table 39. ADC characteristics (HSI must be set to PLL mode)**

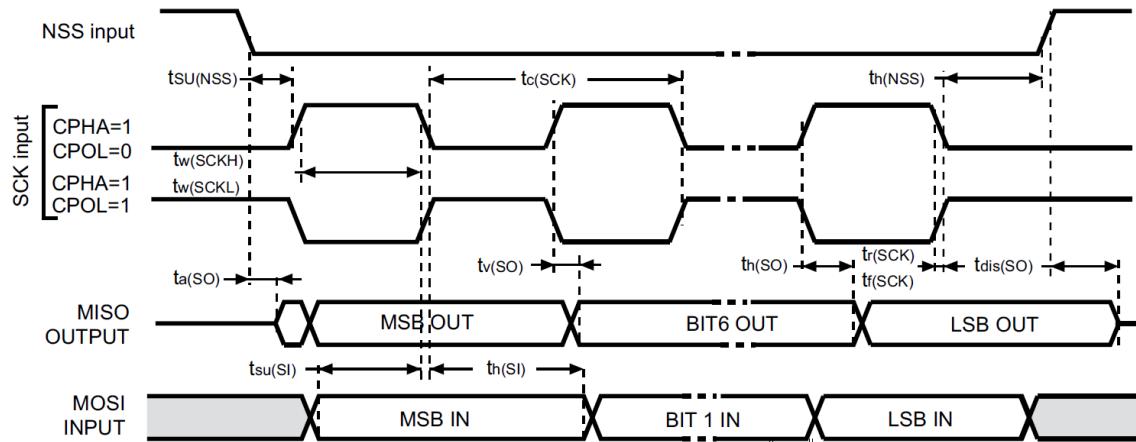
Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Units
Ch_diff_num	Number of channels for differential mode	VFQFPN48, WLCSP49	-	-	4	-
Ch_se_num	Number of channels for single ended mode	VFQFPN48, WLCSP49	-	-	8	-
IBAT_ADCBIAS	ADC biasing consumption at battery	Biassing blocks turned on	-	145	-	µA
IBAT_ADCACTIVE	ADC active consumption at battery	ADC activated in differential mode	-	185	-	µA
VDDA	Analog supply voltage	-	1.2	-	1.32	V
RAIN	Input impedance	In DC	-	250	-	kΩ
Rin	Internal access resistance	VBOOST is enabled for VDD < 2.7 V	-	-	550	Ω
Cin	Input sampling capacitor	-	-	4	-	pF
Ts	Sampling period	Default configuration	-	1	-	µs





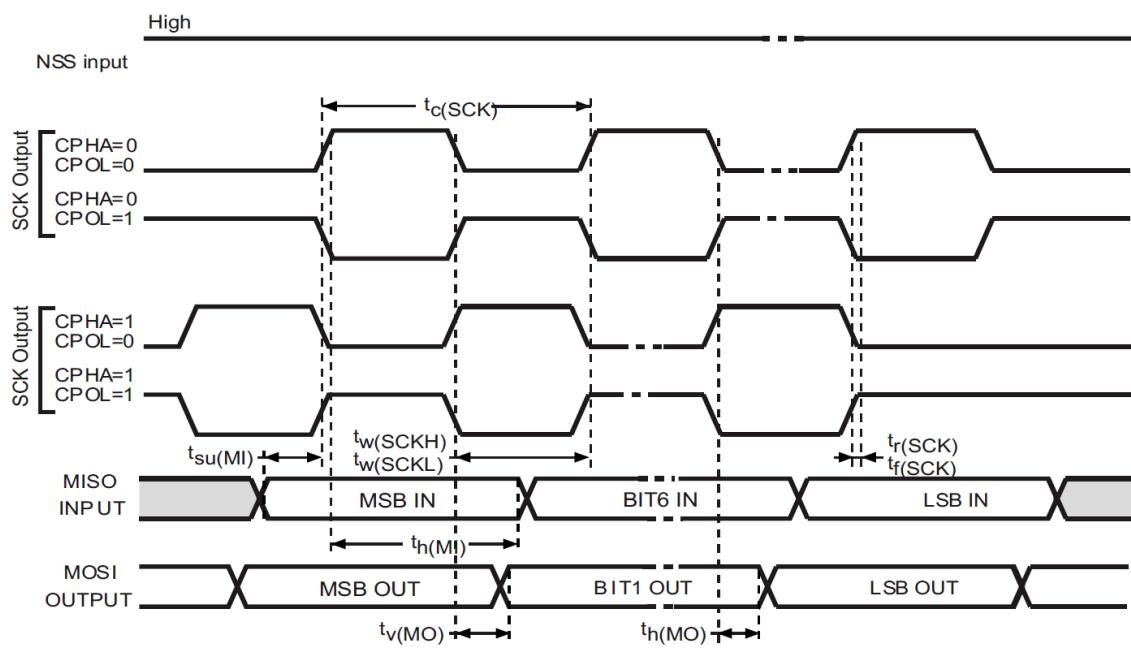


**Figure 17. SPI timing diagram - target mode and CPHA = 1**



DT5747V1

**Figure 18. SPI timing diagram - controller mode**



DT5747V1

## 7 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK is an ST trademark.

### 7.1 Device marking

Refer to technical note "Reference device marking schematics for STM32 microcontrollers and microprocessors" (TN1433) available on [www.st.com](http://www.st.com), for the location of pin 1 / ball A1 as well as the location and orientation of the marking areas versus pin 1 / ball A1.

Parts marked as "ES", "E" or accompanied by an engineering sample notification letter, are not yet qualified and therefore not approved for use in production. ST is not responsible for any consequences resulting from such use. In no event will ST be liable for the customer using any of these engineering samples in production. ST's Quality department must be contacted prior to any decision to use these engineering samples to run a qualification activity.

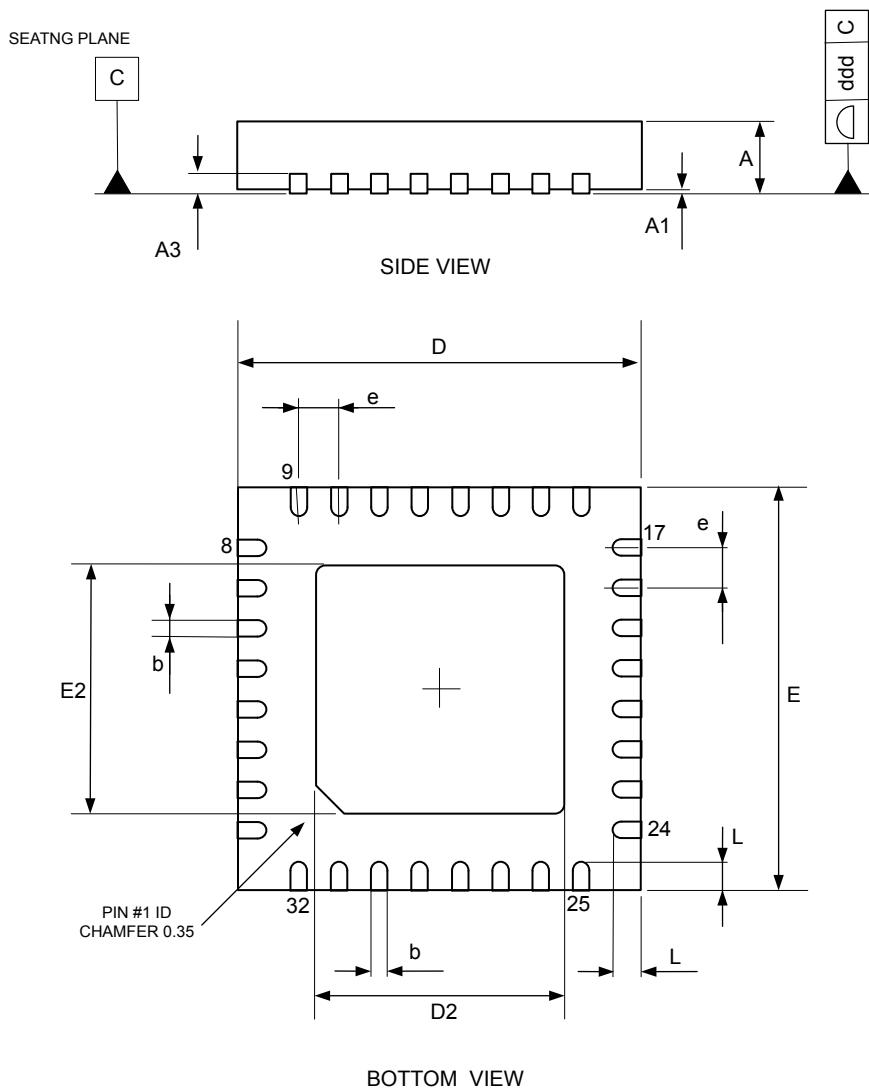
A WLCSP simplified marking example (if any) is provided in the corresponding package information subsection.

## 7.2

## VFQFPN32 package information (42)

This VFQFPN is a 32 lead, 5 x 5 mm, 0.50 mm pitch, very fine pitch quad flat no lead package.

Figure 19. VFQFPN32 - Outline



42\_VFQFPN32\_CALAMEA\_ME\_V1

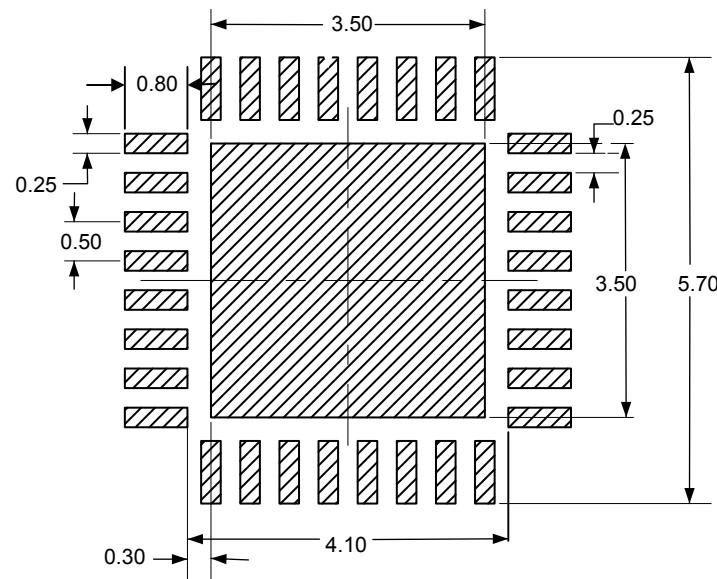
1. Drawing is not to scale.
2. Package outline exclusive of any mold flashes dimensions and metal burrs.
3. Details of terminal 1 are optional but must be located on the top surface of the package by using either a mold or marked features.

**Table 45. VFQFPN32 - Mechanical data**

Symbol	Millimetres			Inches <sup>(1)</sup>		
	Min	Typ	Max	Min	Typ	Max
A <sup>(2)</sup>	0.80	0.90	1.00	0.0315	0.0354	0.0394
A1	0	-	0.05	0	-	0.0020
A3	-	0.20	-	-	0.008	-
b	0.18	0.25	0.30	0.0070	0.0098	0.0118
D	4.90	5.00	5.10	0.1929	0.19	0.2008
E	4.90	5.00	5.10	0.1929	0.19	0.2008
D2	3.60	3.70	3.80	0.1417	0.1457	0.1496
E2	3.60	3.70	3.80	0.1417	0.1457	0.1496
e	-	0.50	-	-	0.0197	-
L	0.30	0.40	0.50	0.0118	0.0157	0.0197
ddd	-	-	0.05	-	-	0.0020

1. Values in inches are converted from mm and rounded to 3 decimal digits.

2. VFQFPN stands for thermally Enhanced very thin fine pitch quad flat package No lead . Very thin profile  $0.80 < A \leq 1.00$  mm.

**Figure 20. VFQFPN32 - Footprint example**


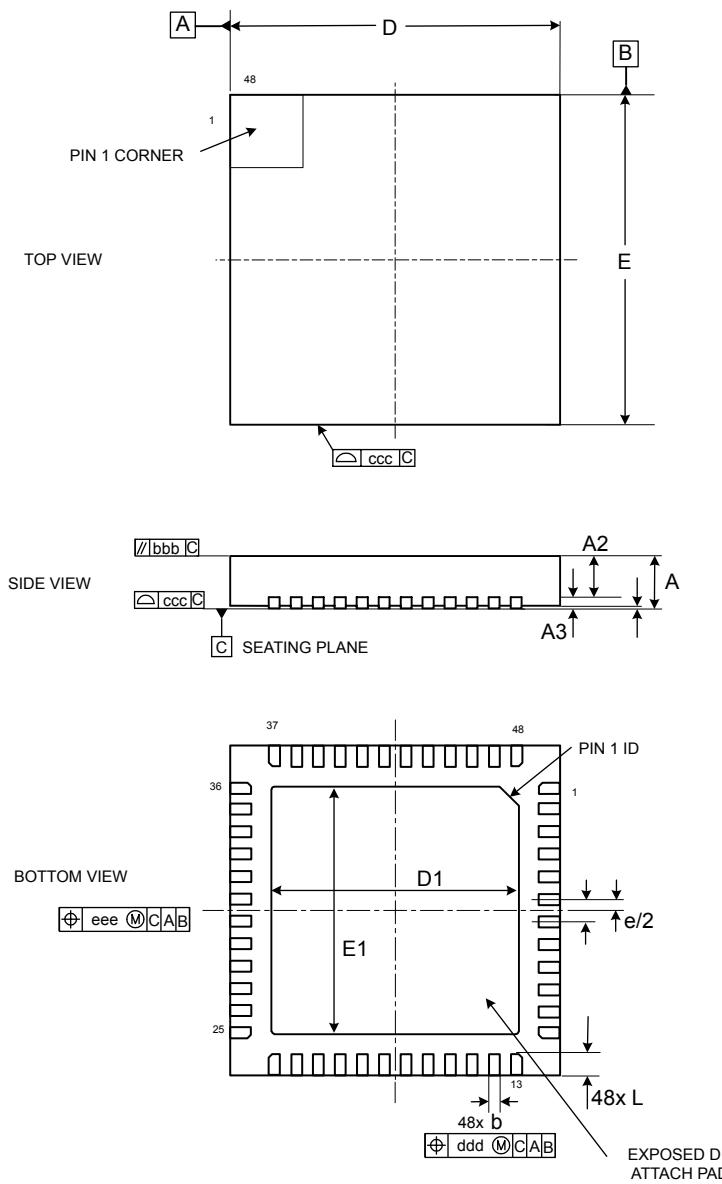
42\_VFQFPN32\_CALAMBA\_FP\_V1

## 7.3

### VFQFPN48 package information

This VFQFPN is a 48 lead, 6 x 6 mm, 0.40 mm pitch, very fine pitch quad flat no lead package.

**Figure 21. VFQFPN48 - Outline**



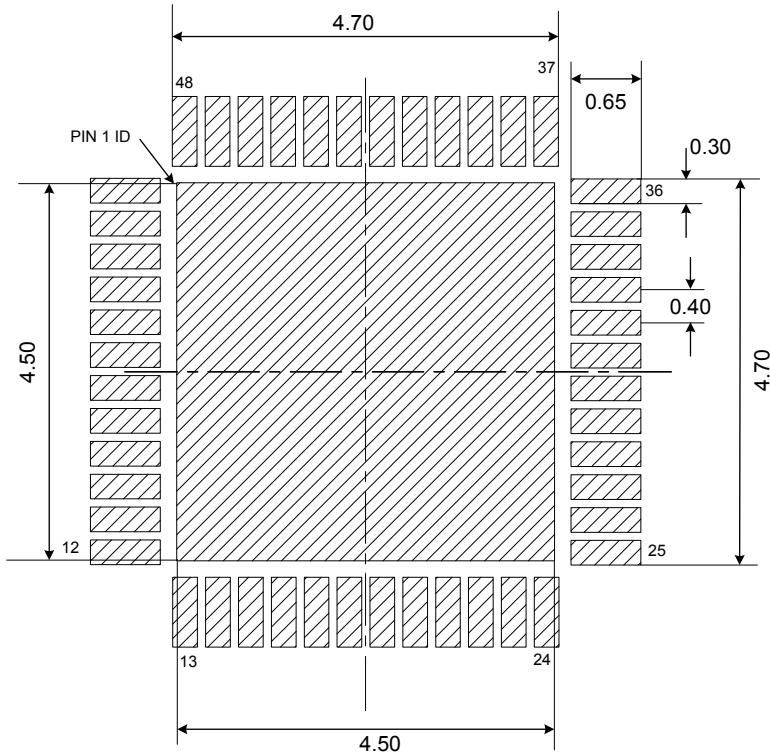
A0BE\_D\_VFQFPN48\_ME\_V1

1. Drawing is not to scale.
2. Dimension and tolerances conform to ASME Y14.5M.
3. Coplanarity applies to leads, corner leads and die attach pad.

**Table 46.** VFQFPN48 - Mechanical data

Symbol	Millimetres			Inches <sup>(1)</sup>		
	Min	Typ	Max	Min	Typ	Max
A	0.80	0.85	0.90	0.0315	0.0335	0.0354
A1	0	0.035	0.05	0	0.0014	0.0020
A2	-	0.65	0.67	-	0.0256	0.0264
A3	0.203 Ref			0.0080 Ref		
b	0.15	0.20	0.25	0.006	0.0080	0.0098
D	6.00 BSC			0.2362 BSC		
D1	4.30	4.40	4.50	0.1693	0.1732	0.1772
E	6.00 BSC			0.2362 BSC		
E1	4.30	4.40	4.50	0.1693	0.1732	0.1772
e	-	0.40 BSC	-	-	0.0157 BSC	-
L	0.40	0.45	0.50	0.0157	0.0177	0.0197
aaa	0.10			0.0039		
bbb	0.10			0.0039		
ccc	0.08			0.0031		
ddd	0.10			0.0039		

1. Values in inches are converted from mm and rounded to 4 decimal digits.

**Figure 22.** VFQFPN48- Footprint example


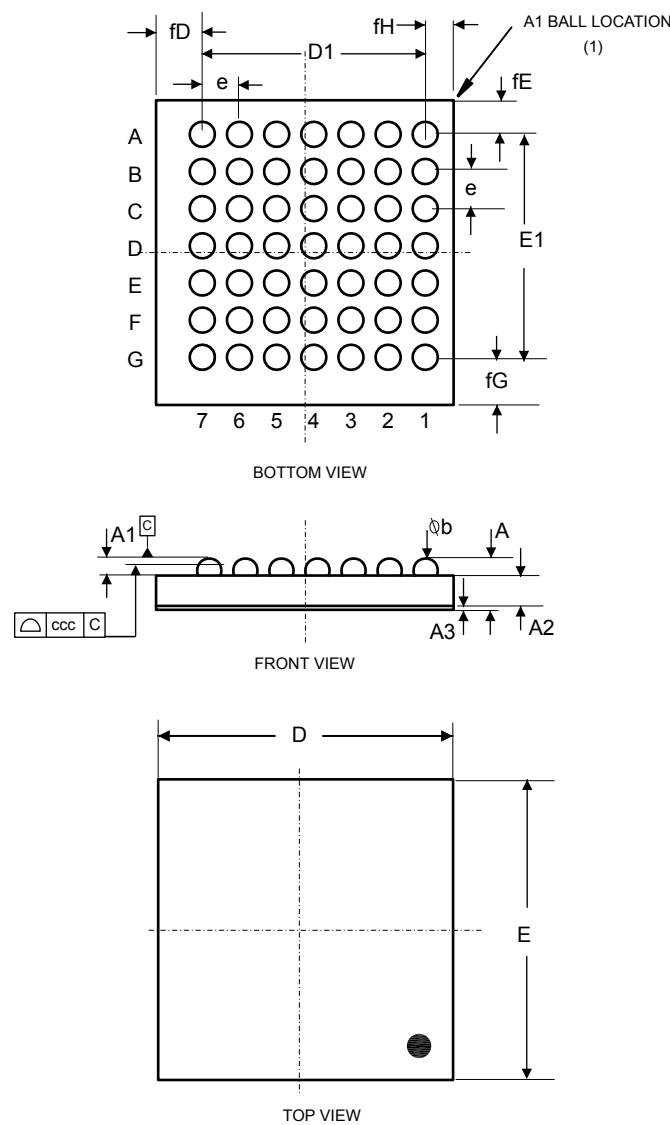
A0BE\_D\_VFQFPN48\_FPB\_V1

## 7.4

### WLCSP49 package information( 01C1)

This WLCSP is a 49-ball, 3.140 x 3.140 mm, 0.40 mm pitch, wafer level chip scale array package.

Figure 23. WLCSP49 - Outline



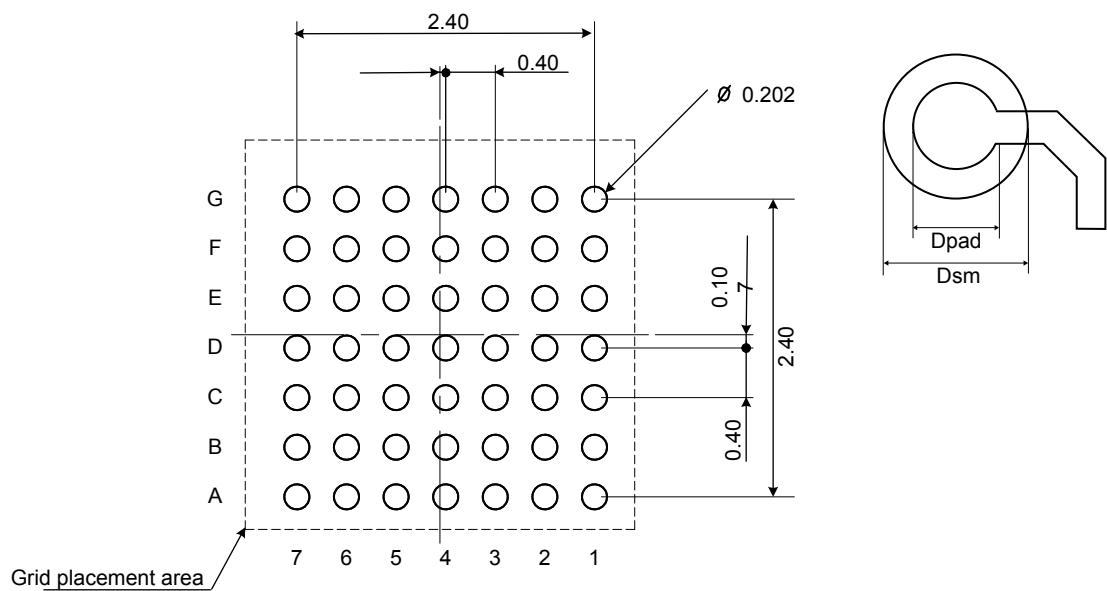
01C1\_WLCSP49\_ME\_V1

1. The terminal A1 on the bumps side is identified by a distinguishing feature (for instance by a circular "clear area" - typically 0.1 mm diameter) and/or a missing bump.  
The terminal A1 on the backside of the product is identified by a distinguishing feature (for instance by a circular "clear area" - typically 0.5 mm diameter).
2. Drawing is not to scale.

**Table 47. WLCSP49 - Mechanical data**

Symbol	millimeters			inches <sup>(1)</sup>		
	Min	Typ	Max	Min	Typ	Max
A	-	-	0.420	-	-	0.0165
A1	0.135	-	-	0.0053	-	-
A2	-	0.225	-	-	0.0088	-
A3	-	0.025	-	-	0.0010	-
b	0.214	0.218	0.222	0.0084	0.0085	0.0087
D	-	3.140	-	-	0.1236	-
D1	-	2.400	-	-	0.0945	-
E	-	3.140	-	-	0.1236	-
E1	-	2.400	-	-	0.0945	-
e	-	0.40	-	-	0.0157	-
fD	-	0.416	-	-	0.0164	-
fE	-	0.263	-	-	0.0103	-
fG	-	0.477	-	-	0.0188	-
fH	-	0.324	-	-	0.0127	-
aaa	-	0.023	-	-	0.0009	-

1. Values in inches are converted from mm and rounded to 4 decimal digits.

**Figure 24. WLCSP49 - Footprint example**


01C1\_WLCSP49\_FP\_V1

1. Dimensions are expressed in millimeters.

**Table 48. WLCSP49 - Example of PCB design rules**

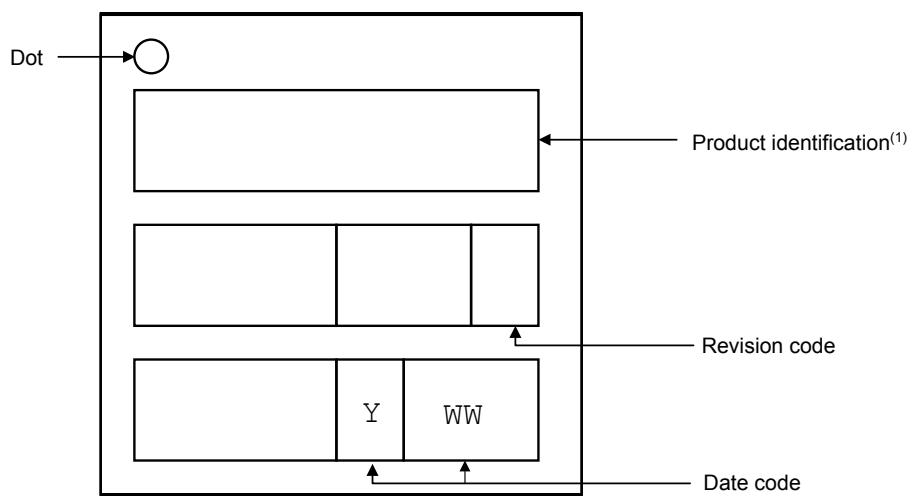
Dimension	Values
Pitch	0.4 mm
Dpad	0,225 mm
Dsm	0.290 mm typ. (depends on soldermask registration tolerance)
Stencil opening	0.250 mm
Stencil thickness	0.100 mm

#### 7.4.1 Device marking for WLCSP49

The following figure gives an example of topside marking versus ball A1 position identifier location.

The printed markings may differ depending on the supply chain.

Other optional marking or inset/upset marks, which depend on supply chain operations, are not indicated below.

**Figure 25. WLCSP49 marking example**

DT58390

1. Parts marked as "ES", "E" or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not approved for use in production. ST is not responsible for any consequences resulting from such use. In no event will ST be liable for the customer using any of these engineering samples in production. ST's Quality department must be contacted prior to any decision to use these engineering samples to run a qualification activity.

## 7.5

### Thermal characteristics

The maximum chip junction temperature ( $T_{J\max}$ ) must never exceed the values in general operating conditions.

The maximum chip-junction temperature,  $T_J$  max., in degrees Celsius, can be calculated using the equation:

$$T_{J\max} = T_A\max + (PD\max \times \theta_{JA}) \quad (1)$$

where:

- $T_A$  max. is the maximum ambient temperature in °C
- $\theta_{JA}$  is the package junction-to-ambient thermal resistance, in °C/W
- PD max. is the sum of PINT max. and PI/O max. (PD max. = PINT max. + PI/O max.)
- PINT max. is the product of IDD and VDD, expressed in Watt. This is the maximum chip internal power

PI/O max represents the maximum power dissipation on output pins:

- $PI/O\max = \sum (VOL \times IOL) + \sum ((VDD - VOH) \times IOH)$

taking into account the actual VOL / IOL and VOH / IOH of the I/Os at low and high level in the applications.

Note: When the SMPS is used, a portion of the power consumption is dissipated into the external inductor, therefore reducing the chip power dissipation. This portion depends mainly on the inductor ESR characteristics.

Note: As the radiated RF power is quite low (< 4 mW), it is not necessary to remove it from the chip power consumption.

Note: RF characteristics (such as: sensitivity, Tx power, consumption) are provided up to 85 °C.

**Table 49. Package thermal characteristics**

Symbol	Parameter	Value	Unit
$\theta_{JA}$	Thermal resistance junction-ambient VFQFPN48 – 6 mm x 6 mm	25.1	°C/W
	Thermal resistance junction-ambient VFQFPN32 - 5 mm x 5 mm	26.9	
	Thermal resistance junction-ambient WLCSP49 – 0.4 mm pitch	-	

#### 7.5.1

##### Reference documents

- JESD51-2 Integrated Circuits Thermal Test Method Environment Conditions - Natural Convection (Still Air) available on [www.jedec.org](http://www.jedec.org).
- For information on thermal management, refer to application note "Guidelines for thermal management on STM32 applications" (AN5036) available on [www.st.com](http://www.st.com).

## 8 Ordering information

Example:	STM32	WB	07	K	C	V	6	TR	TR
<b>Device family</b>									
STM32 = Arm®-based 32-bit microcontroller									
<b>Product type</b>									
WB = wireless Bluetooth									
<b>Device subfamily</b>									
07 = full set of features (64 KB RAM)									
06 = full set of features (32 KB RAM)									
<b>Pin count</b>									
K = 32 pins									
C = 48 pins									
<b>Flash memory size</b>									
C = 256 Kbytes									
<b>Package</b>									
F = WLCSP ECOPACK2									
V = VFQFPN ECOPACK2									
<b>Temperature range</b>									
6 = industrial temperature range, -40 to 85 °C									
7 = industrial temperature range, -40 to 105 °C									
<b>Packing</b>									
TR = tape and reel									

**Note:** For a list of available options (such as speed and package) or for further information on any aspect of this device, contact your nearest ST sales office.

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## Revision history

**Table 50. Document revision history**

Date	Revision	Changes
13-Jun-2024	1	Initial release.
04-Sep-2024	2	Updated VFQFPN32 package information
26-Sep-2024	3	Updated: <ul style="list-style-type: none"><li>• Table 6. STM32WB0xxC pin-ball definition</li><li>• Table 7. Alternate function port A</li><li>• Table 8. Alternate function port B</li></ul>

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